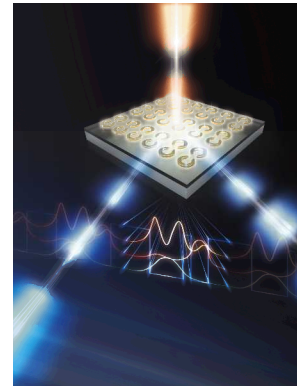
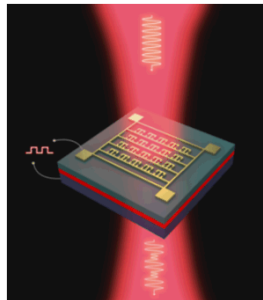
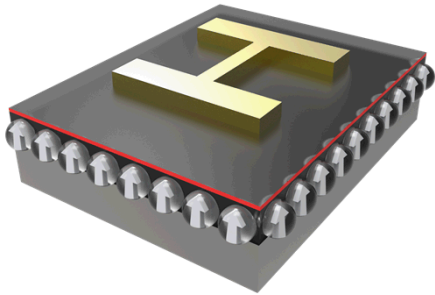


Active Dielectric and Metallic Metasurfaces: Strong Coupling, Tuning and Nonlinearities



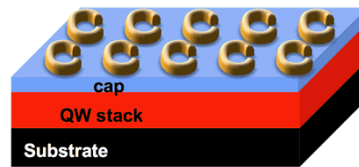
Igal Brener

Sandia National Labs &
Center for Integrated Nanotechnologies (CINT)

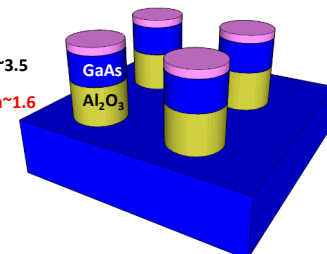
ibrener@sandia.gov

Outline

- Tunable Metasurfaces: overview
- Control of Strong Coupling for tunable behavior
- Harmonic generation from metallic metasurfaces coupled to intersubband transitions in semiconductor quantum wells

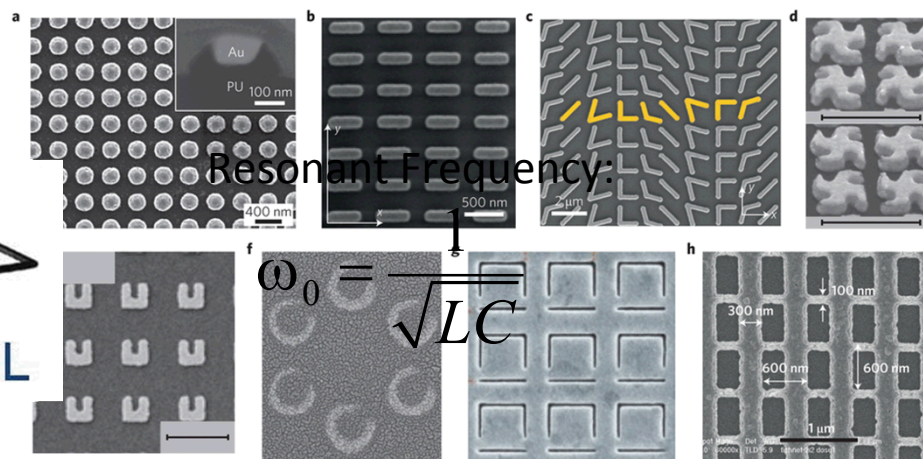
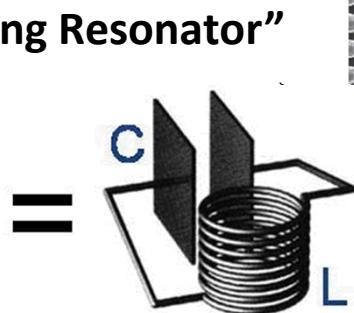
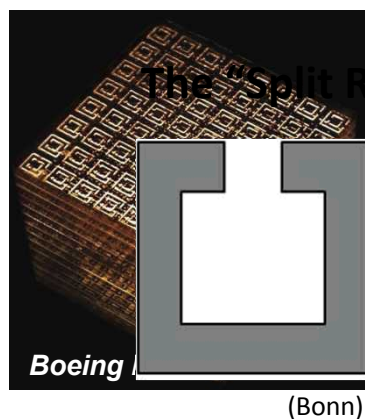


- Harmonic generation from all-dielectric metasurfaces



2D Metallic Metamaterials (“Metasurfaces”)

3D (for some applications, loss is a good thing) 2D



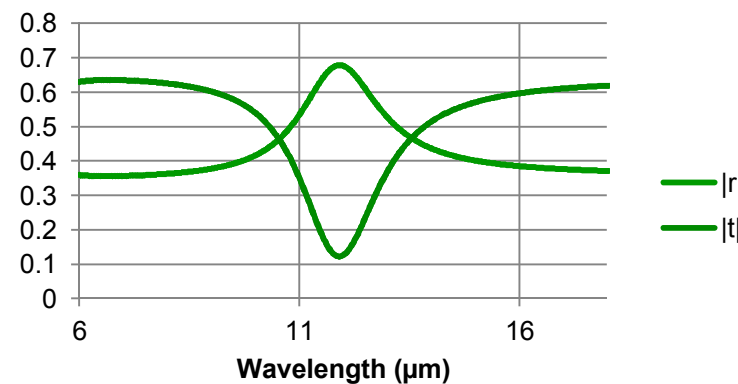
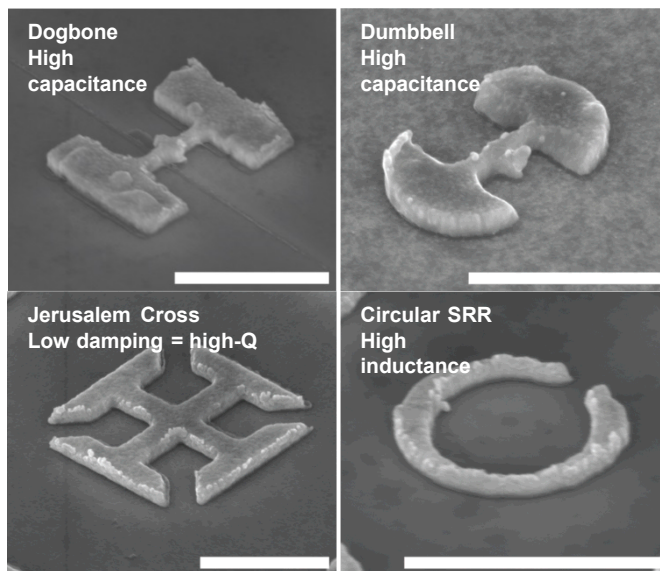
Resonant Frequency:

$$\omega_0 = \frac{1}{\sqrt{LC}}$$

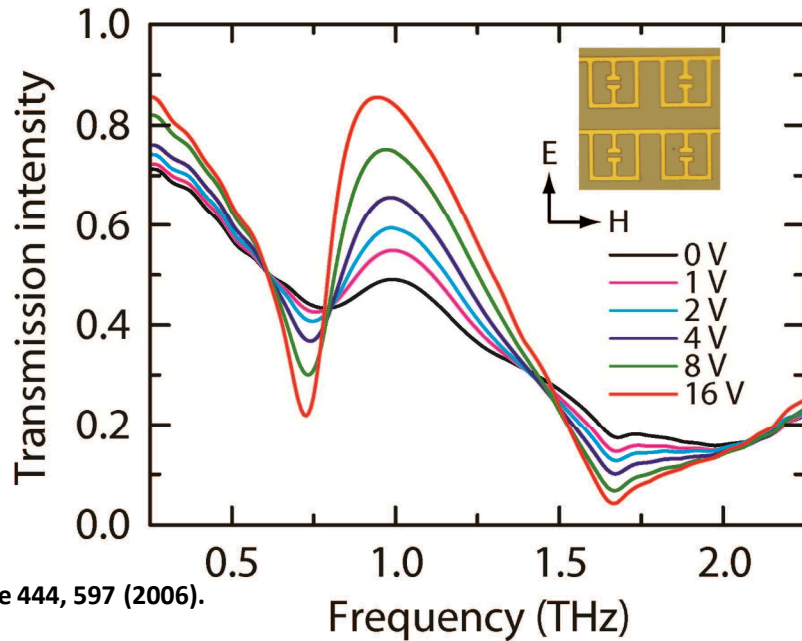
Nature Photonics 8, 889 (2014)

Even for different shapes, many metallic resonators behave like LCR circuits

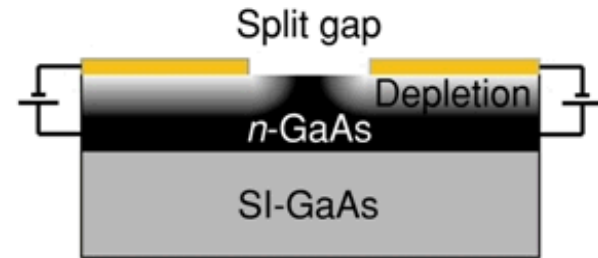
$\sim \lambda/10$



Early Days of Tunable Metasurfaces

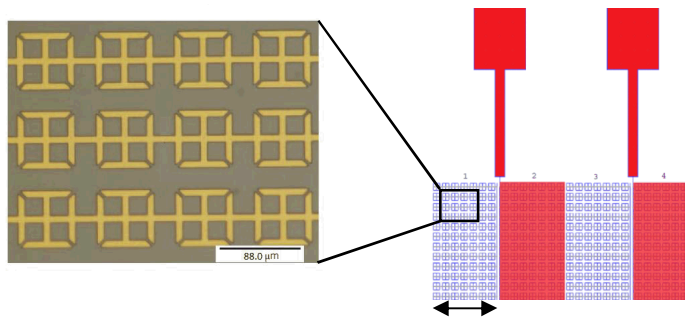


Nature 444, 597 (2006).

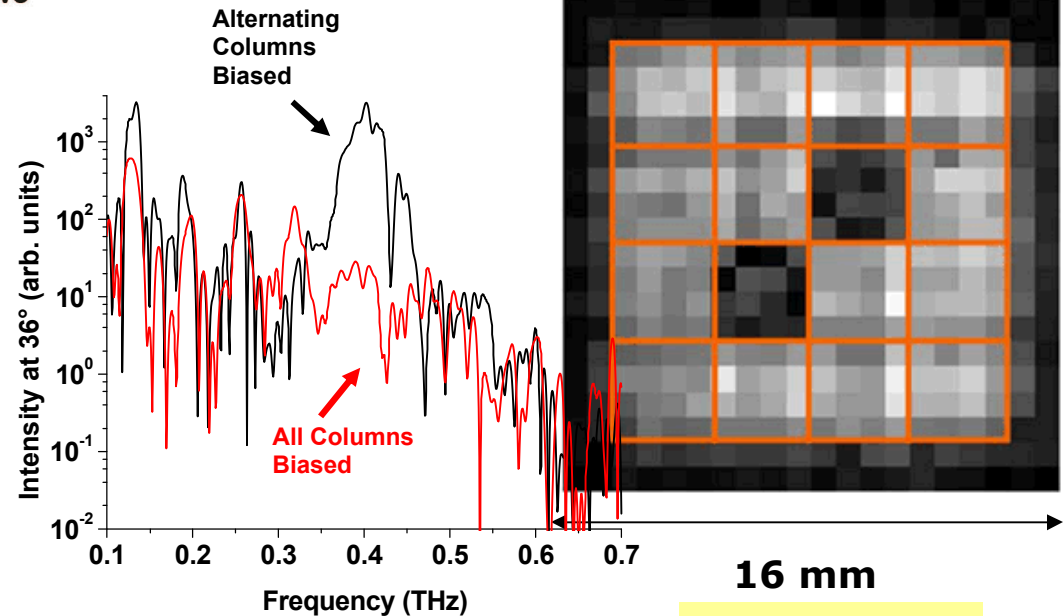


This works by increasing the damping (ϵ_2).

0.36 THz, 4x4 SLM



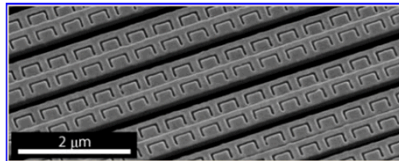
Appl. Phys. Lett., 104, 091115 (2014).



Appl. Phys. Lett. 94,
213511 (2009)

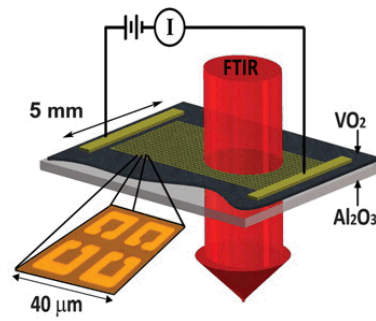
Tunable Metasurfaces: Other Approaches

MEMS approaches



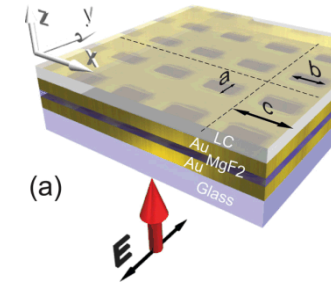
Pryce, NL (2010)
Ou *et. al.* (Zheludev), (2011). NL 11, 2142 (2011).

Phase transitions in VO₂



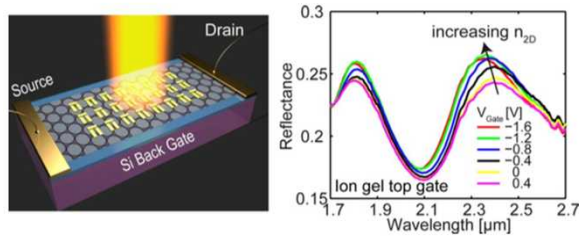
T. Driscoll, Science (2009)

Re-orientation of liquid crystals

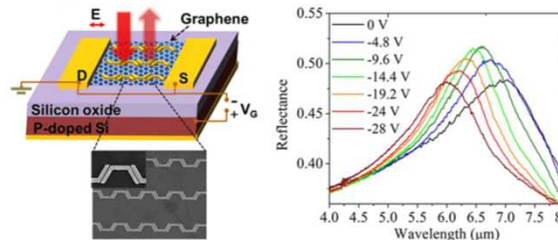


A. Minovich, APL (2012)

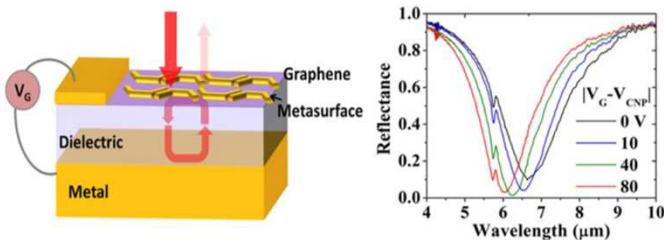
Graphene-based modulation



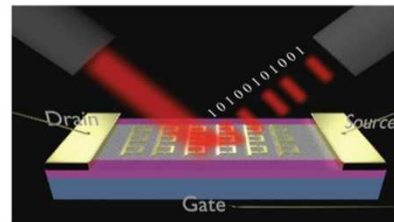
Emani *et. al.* (Boltasseva), NL 14, 78 (2014)



Yao *et. al.* (Capasso), NL 14, 214 (2014)

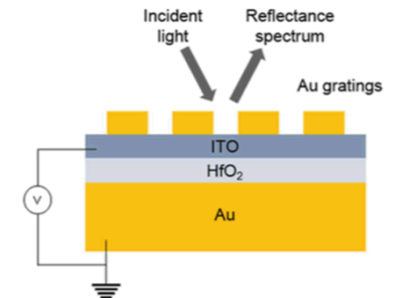


Yao *et. al.* (Capasso), NL 14, 6526 (2014)

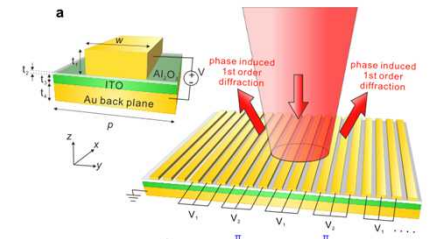


Dabidian *et. al.* (Shvets), ACS Phot. 2, 216 (2015) (2015)

Depletion/Accumulation ITO



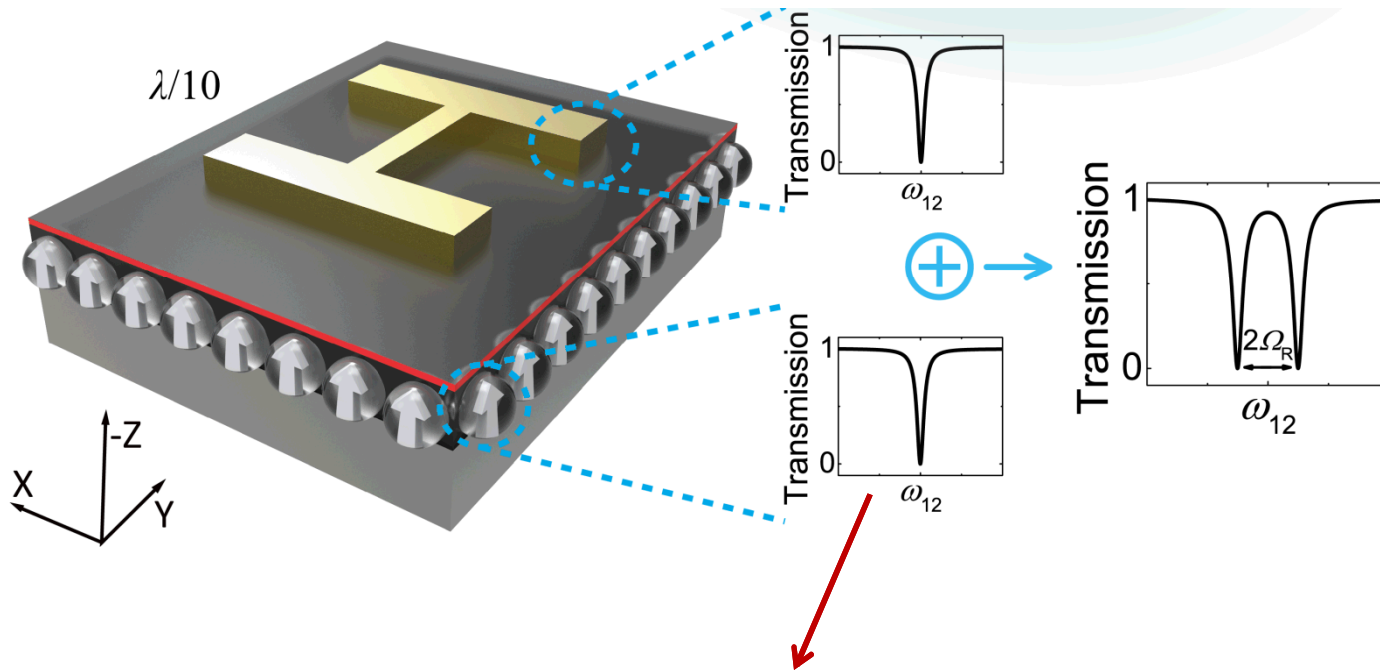
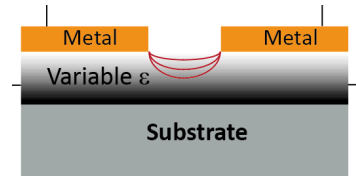
Part *et. al.* (Brongersma), Sci. Rep. 2015



Huang *et. al.* (Atwater), arXiv:1511.09380

Controlled Coupling as Tuning Mechanism

MM resonators create strong optical fields that lead to strong coupling



Optical Phonons: Nano Letters 11, 2104 (2011)

Epsilon Near Zero modes: Nano Letters 13, 5391 (2013)

Intersubband Transitions: Nature Communications 4, (2013)



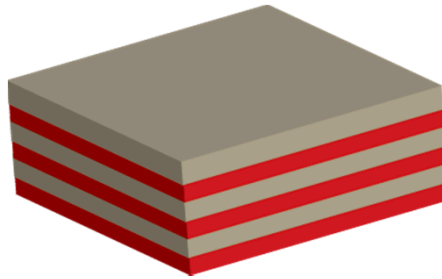
Strong Coupling to Intersubband Transitions in Quantum Wells



Alex Benz

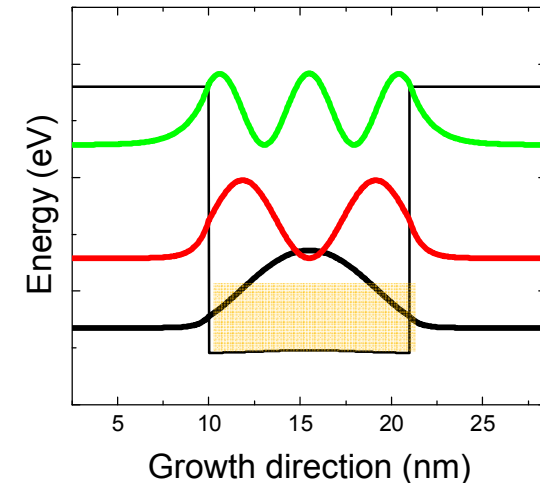
- Scalable (far IR to near IR), Mature, Versatile

Opt. Express 20, 6584 (2012),
APL 98, 203103 (2011)

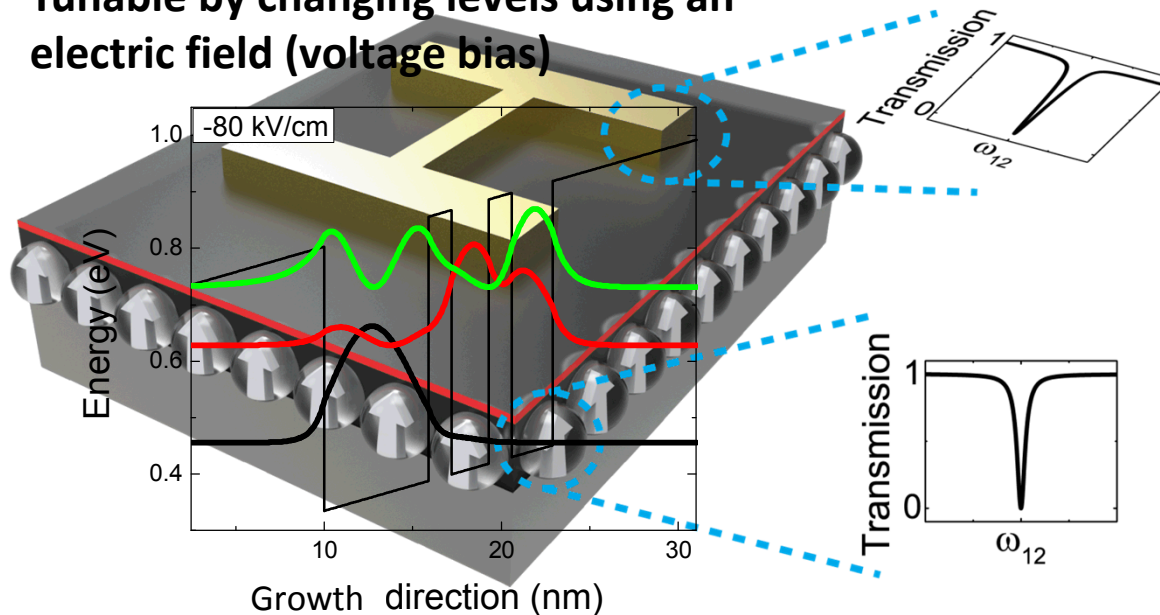


$\hat{z}$

$$\epsilon_{xx} = \epsilon_{yy} \neq \epsilon_{zz}$$

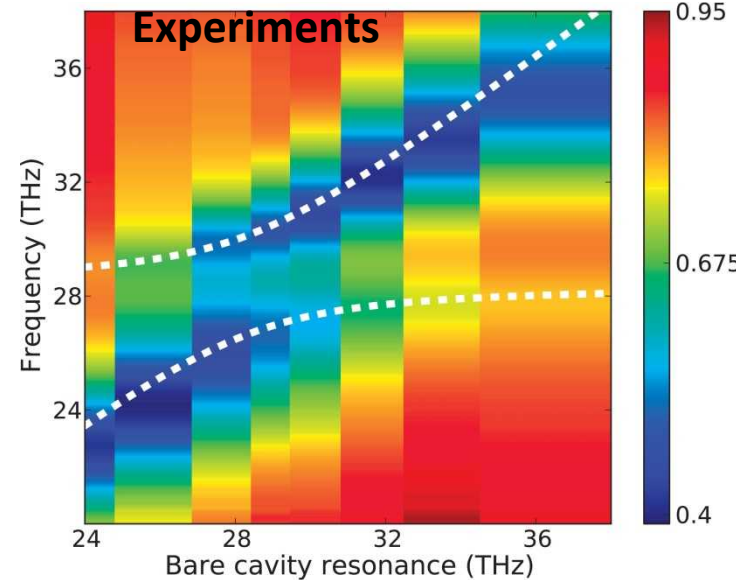
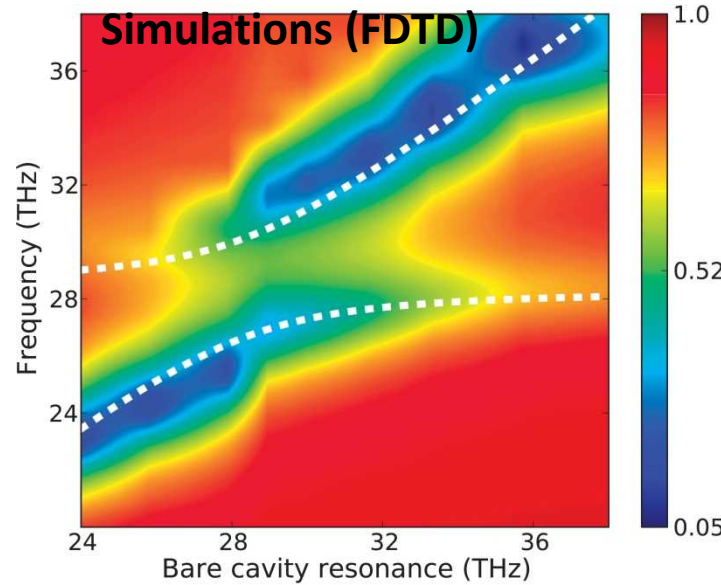
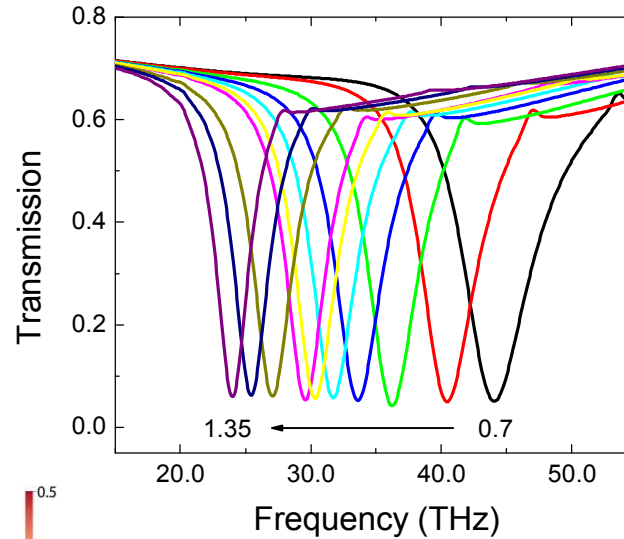
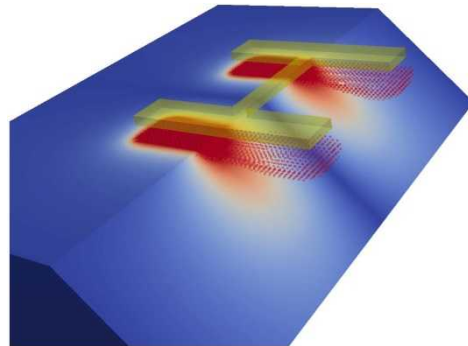
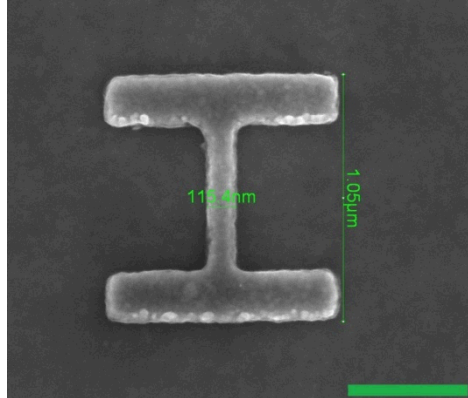


Tunable by changing levels using an electric field (voltage bias)



Strong Coupling Theory vs. Experiment

“Dogbone” resonators



Rabi frequency depends on simple parameters

Plasma frequency

$$\Omega_R = \sqrt{f_W \omega_p} / 2$$

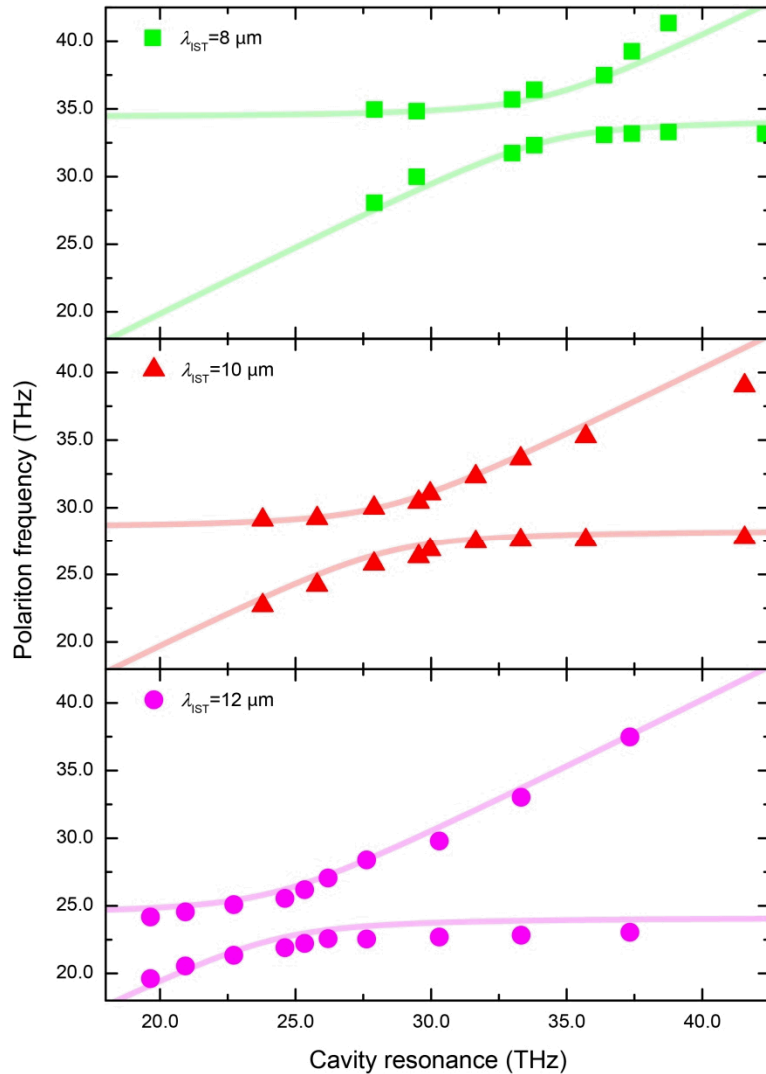
Geometry factor



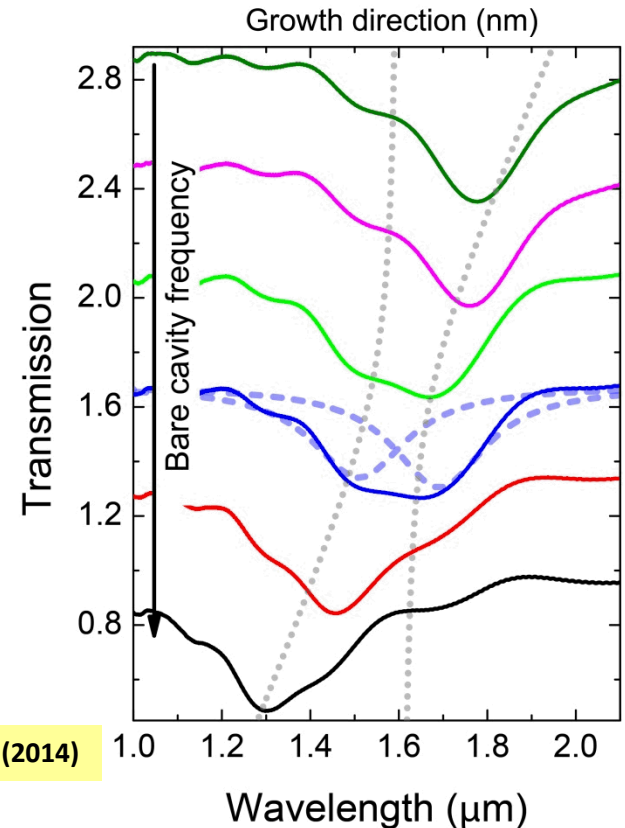
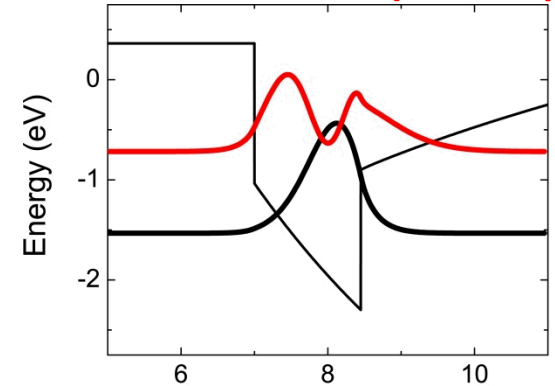
Alex Benz

From Mid-IR to Near IR

InGaAs QWs (mid IR)

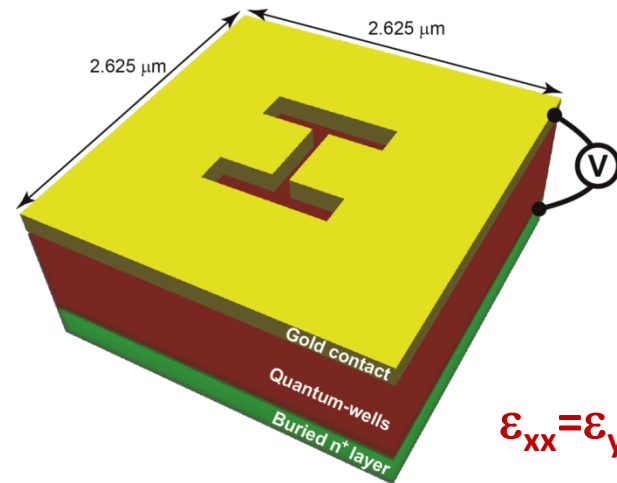


GaN QWs (near IR)

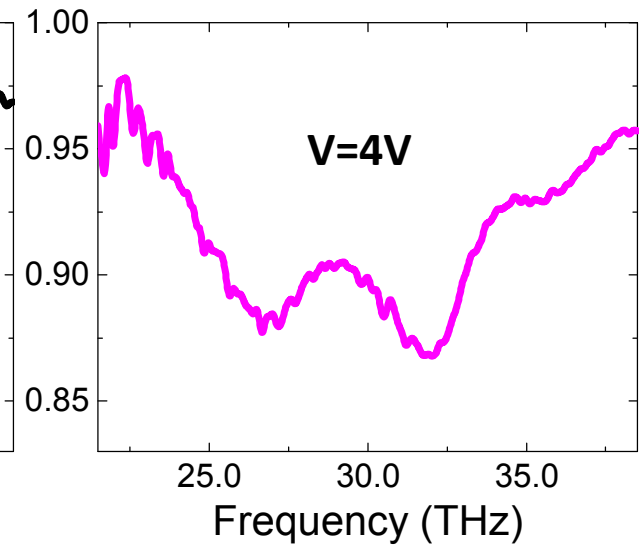
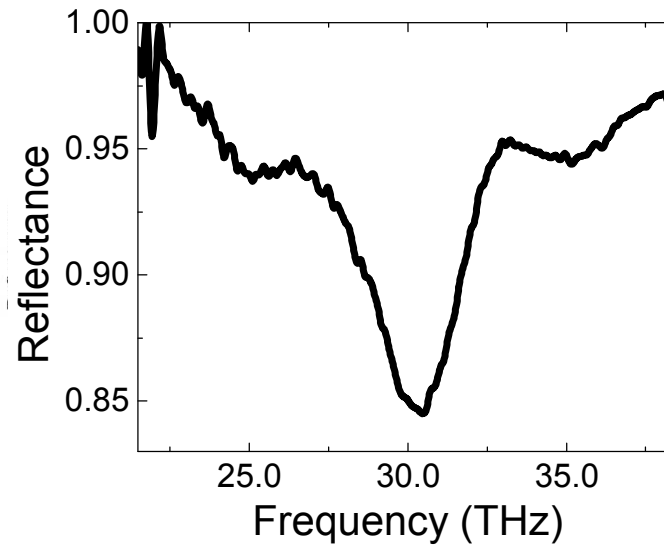
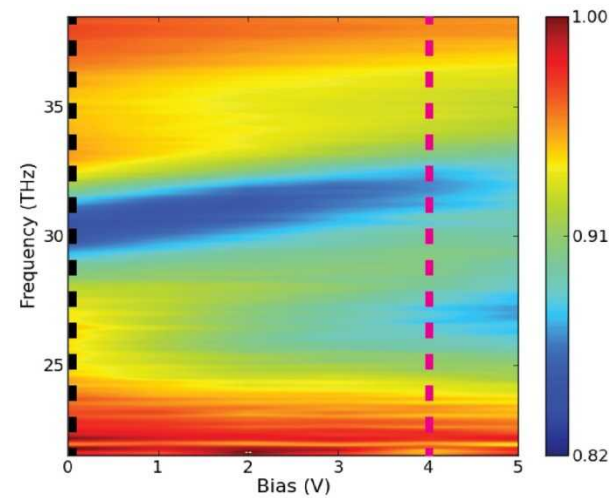
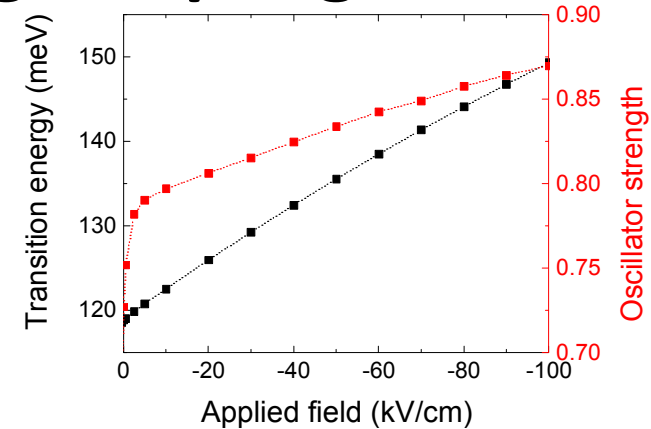
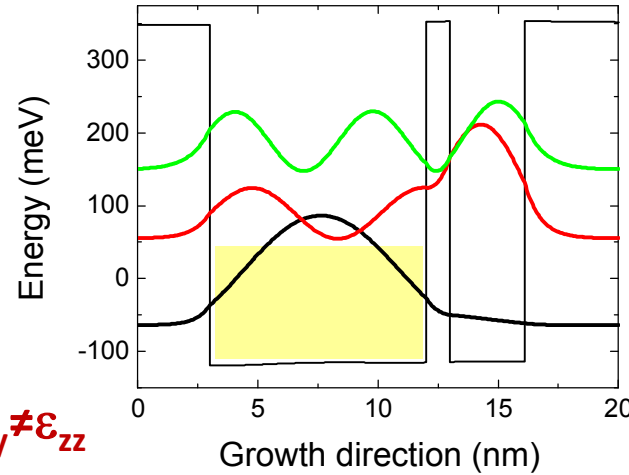


ACS Photonics (2014)

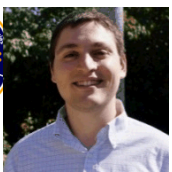
Electrically Tunable Strong Coupling



$$\epsilon_{xx} = \epsilon_{yy} \neq \epsilon_{zz}$$



Upper polariton shifted by 2.5 THz (~8% of center frequency)

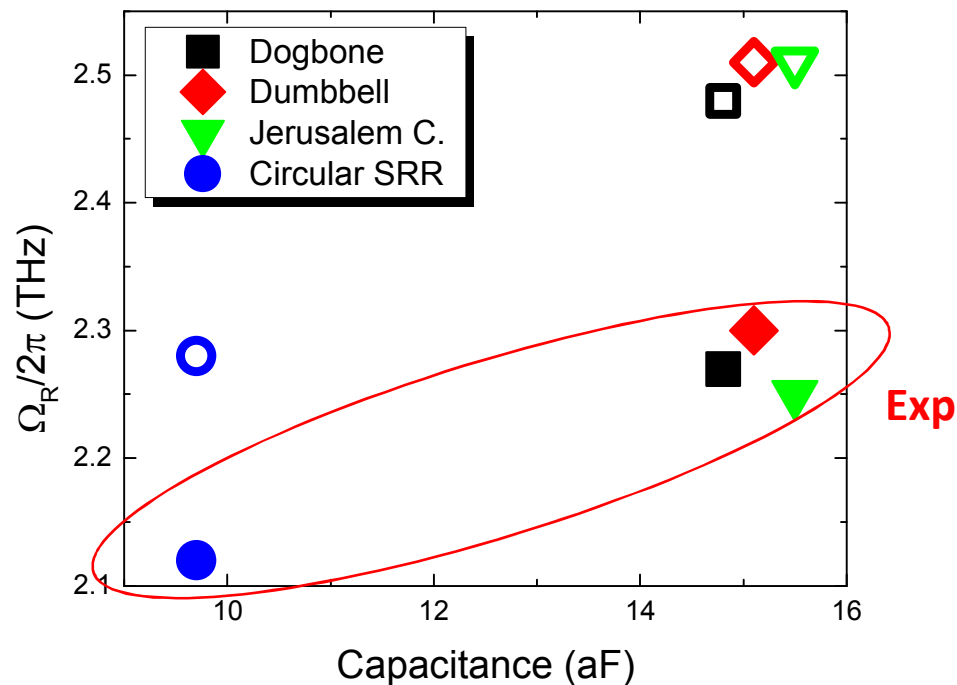
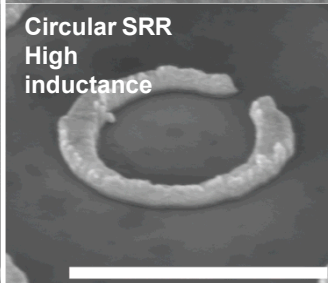
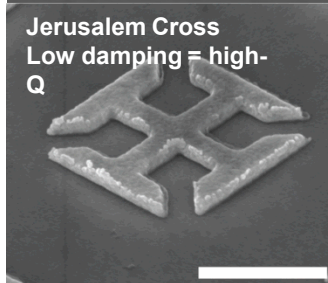
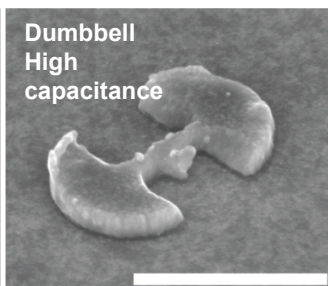
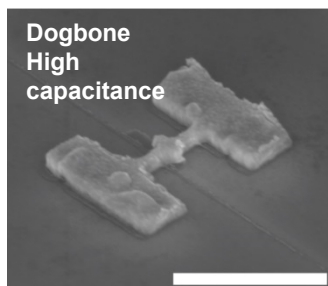
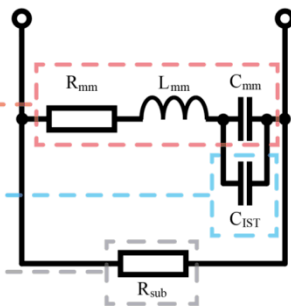
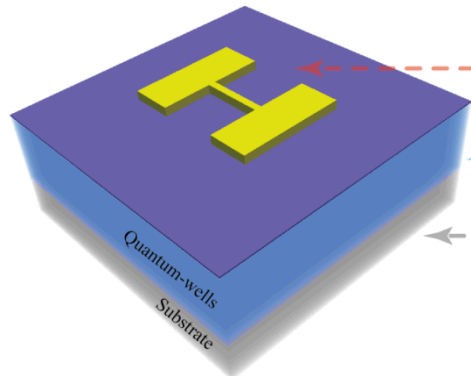


Salvo



Alex

Rabi Frequency vs. Geometry



Physical Review B89, 165133 (2014)
NanoLetters 15, 1959 (2015)

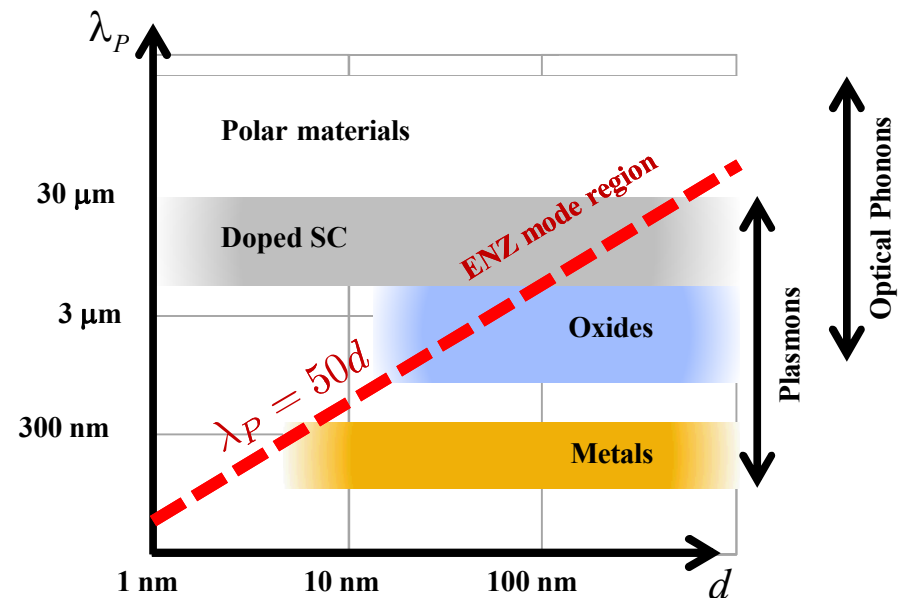
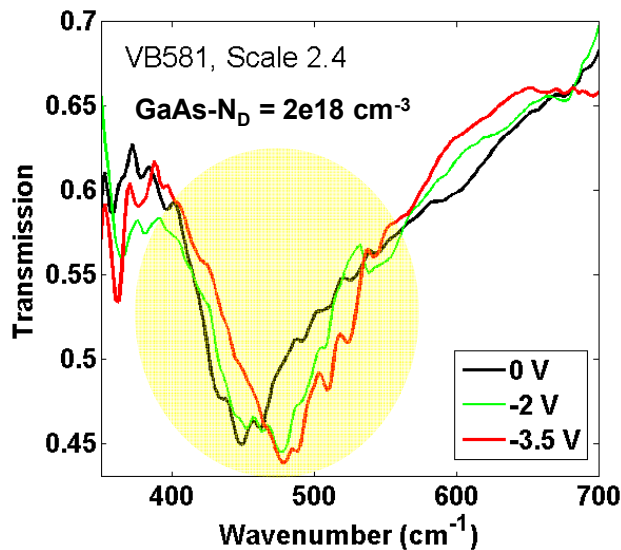
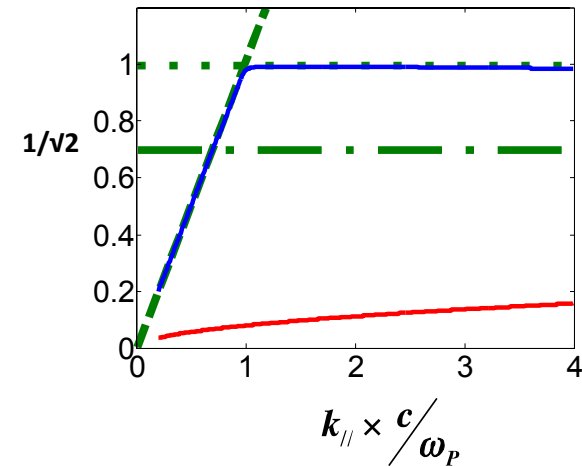
- Larger capacitance leads to larger Rabi splitting

Tunable Metasurfaces: Coupling to Epsilon Near Zero Modes

Very thin layers of a Drude material support Epsilon Near Zero modes

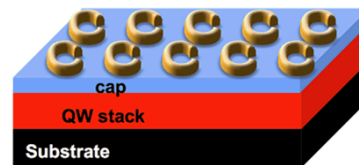
$$d \ll \frac{\lambda_P}{50}$$

Phys. Rev. B RC. 91, 121408 (2015)

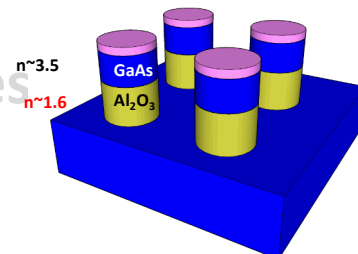


Outline

- Tunable Metasurfaces: overview
- Control of Strong Coupling for tunable behavior
- **Harmonic generation from metallic metasurfaces coupled to intersubband transitions in semiconductor quantum wells**



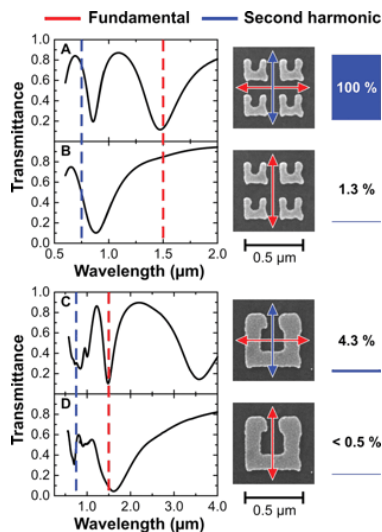
- Harmonic generation from all-dielectric metasurfaces



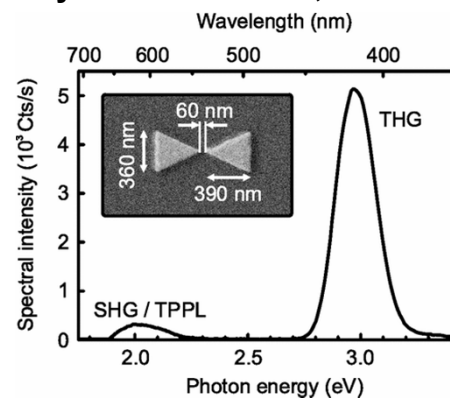
Nonlinear Metasurfaces: Harmonic Generation from Metallic Resonators

- Harmonic generation has been observed from planar metamaterials (“metasurfaces”) and plasmonic arrays.

First reports: Science 502, 313 (2006)



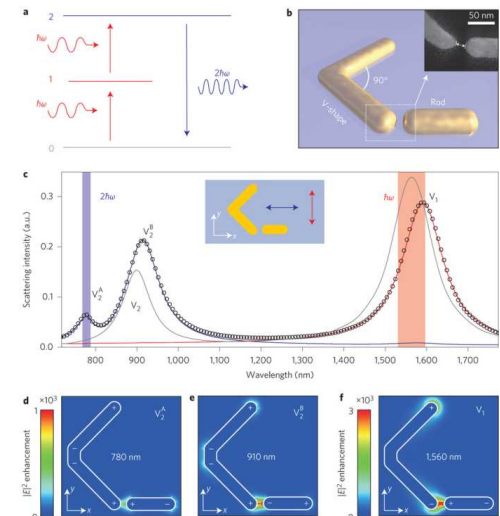
Other geometries: Phys. Rev. Lett. 103, 257404 (2009)



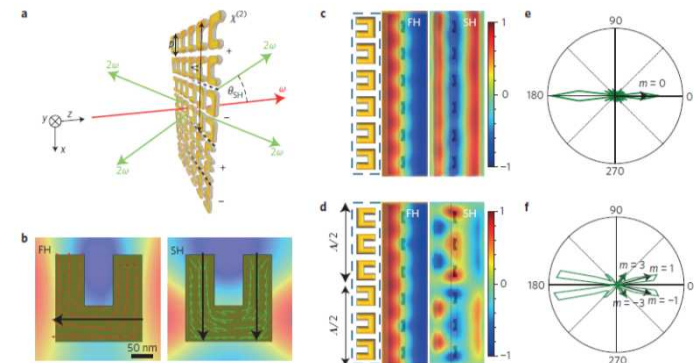
And many more....

Efficiencies have been **very, very low!**

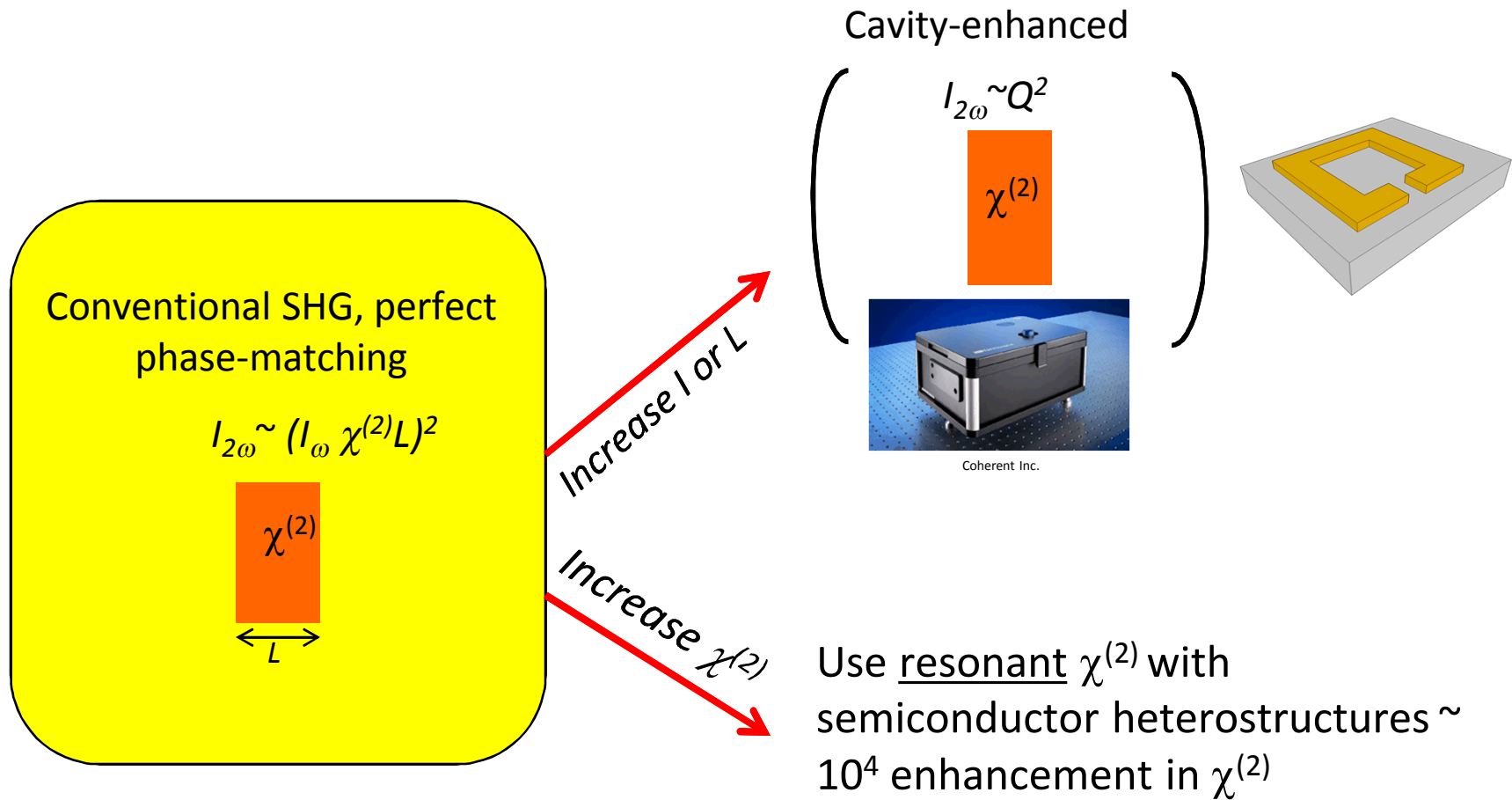
Mode Matching: Nature Nanotechnology 10, 412 (2015)



Metamaterials Photonic Crystals: Nature Photonics 9, 180 (2015)

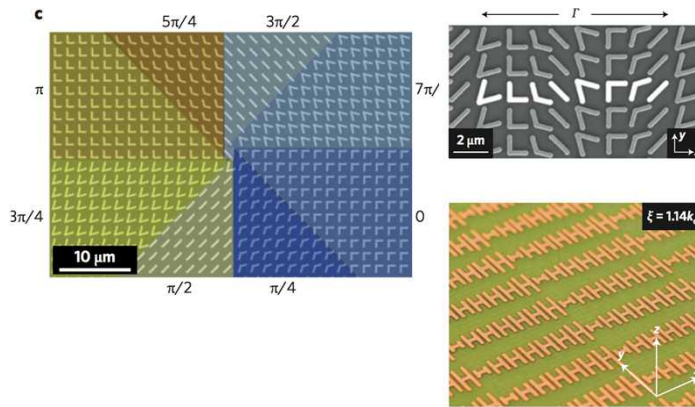


How Metasurfaces on Semiconductors Can Be Used for Enhanced Optical Nonlinearities

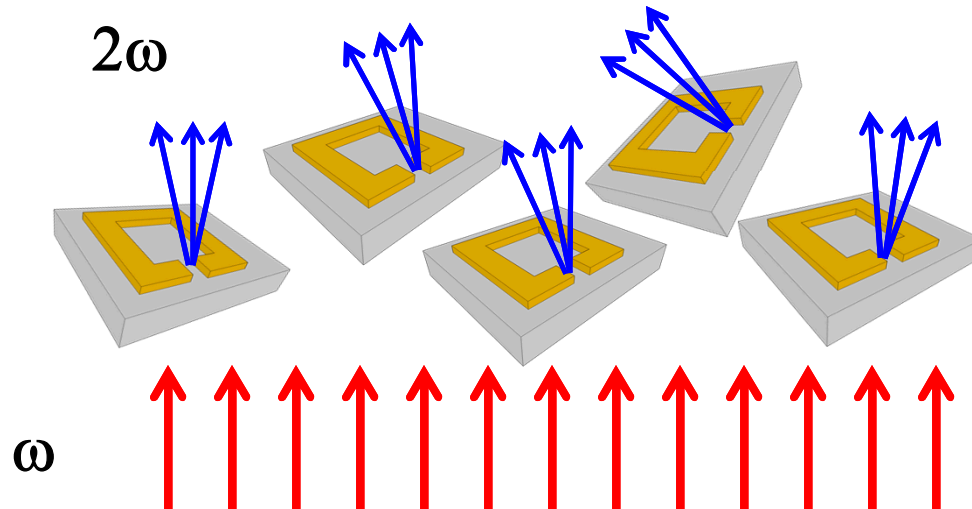


Metasurfaces Provide New Functionality for Harmonic Generation

Metallic Metasurfaces have been used extensively for beam/phasefront/polarization manipulation: *this is all degenerate*

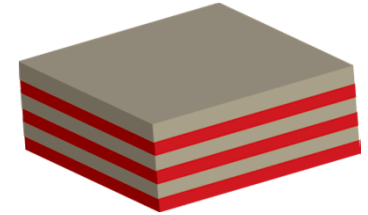
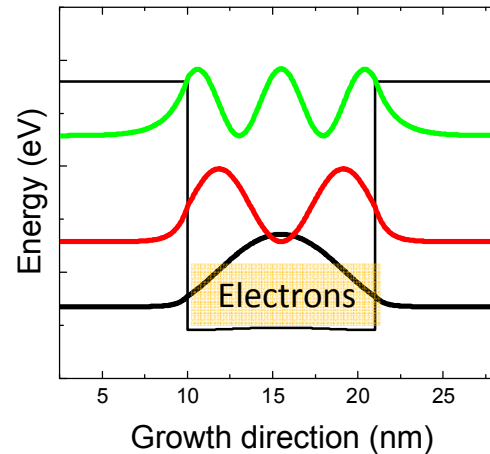


(Shalaev, Capasso, Zhou, Zheludev, etc..)

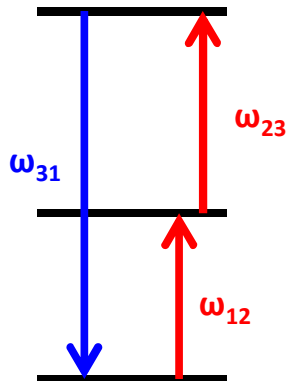


Resonant Optical Nonlinearities: Intersubband Transitions in Quantum Wells

Electronic levels and wavefunctions can be engineered with semiconductor heterostructures



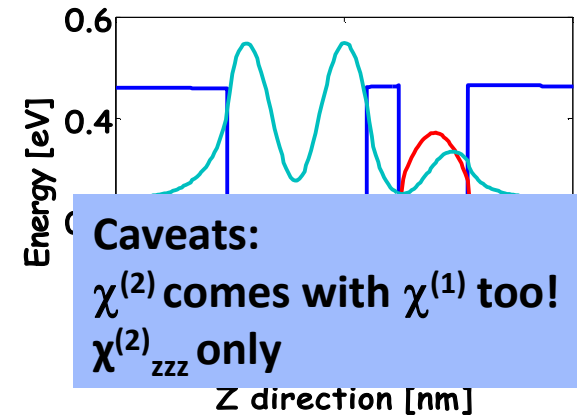
Resonant optical nonlinearities can be engineered too:



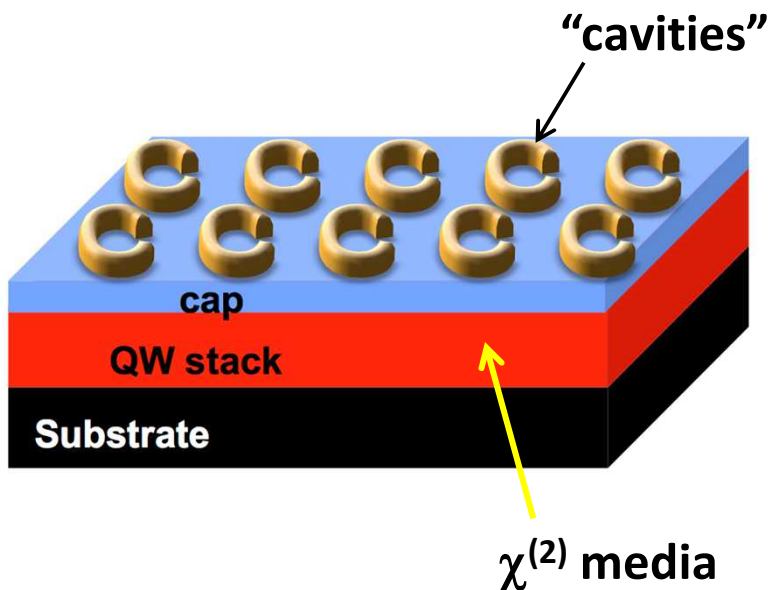
$$\chi^{(2)}(\omega) \propto \frac{N \cdot z_{12} z_{23} z_{13}}{(\omega - \omega_{12} - i\Gamma_{12})(2\omega - \omega_{13} - i\Gamma_{13})}$$

$$z_{ij} \propto \langle \Psi_i | \vec{R} | \Psi_j \rangle$$

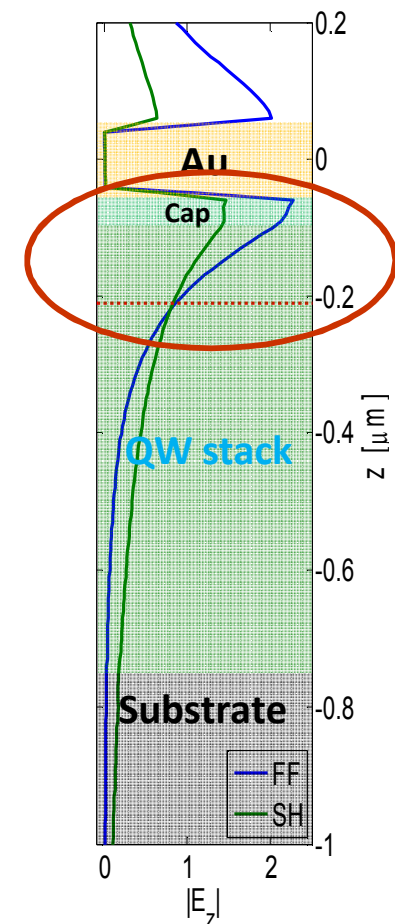
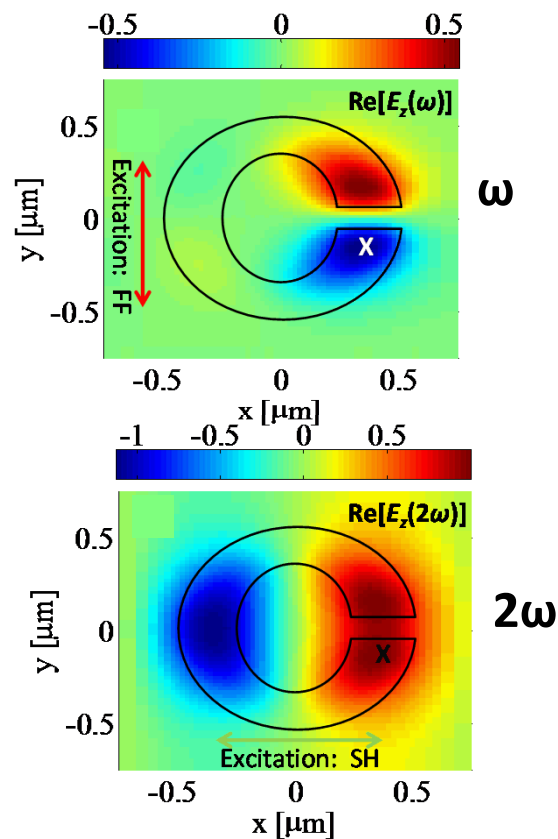
~250 nm/V - QWs
10s of pm/V - LiNbO₃



Metasurfaces Coupled to Resonant $\chi^{(2)}$

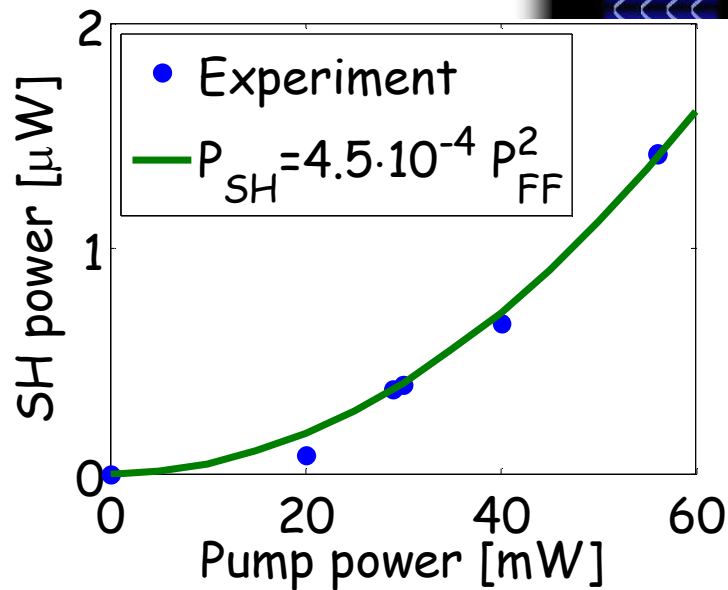
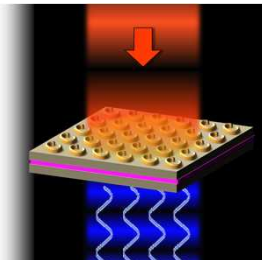


Resonators are designed to have resonances at 30 & 60 THz (5 & 10 μm)

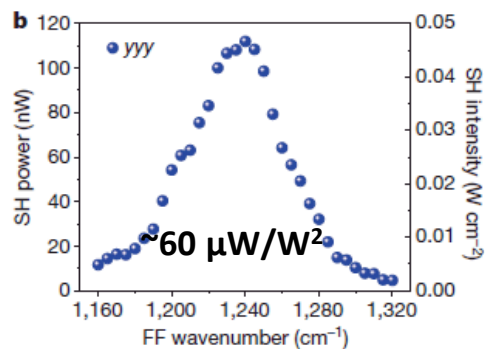
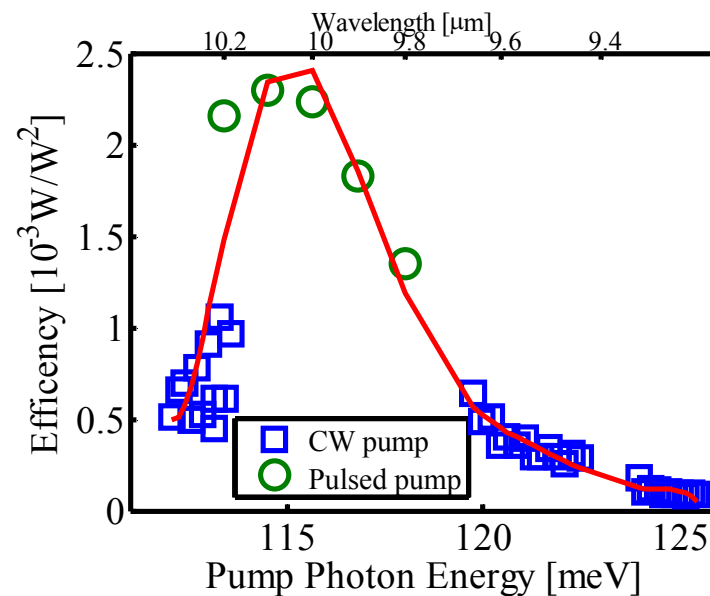


SHG: Power and Frequency Dependence

Pump: CW CO₂ laser



max efficiency: $\sim 2.3 \text{ mW/W}^2$



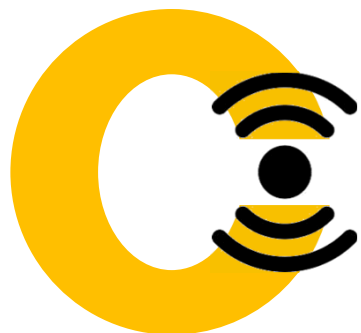
- Saturation is an issue
- Max. conversion efficiencies of few % are possible
- Added functionality is the advantage



Omri

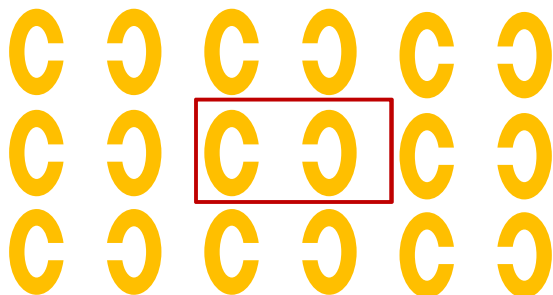
Salvo

SHG Beam Manipulation



“edge-fed dipole”

flipping induces π phase shift

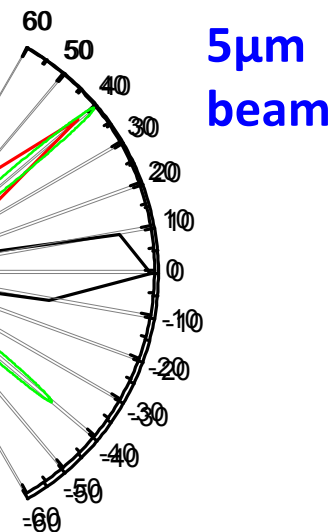


Period determines angular separation

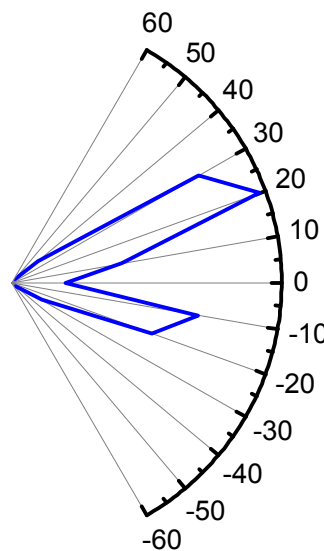
10 μ m pump



Uniform Array



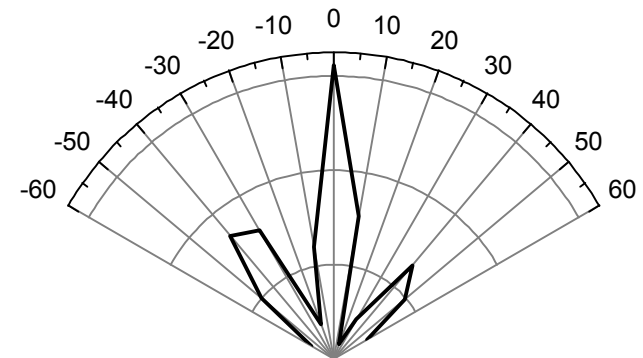
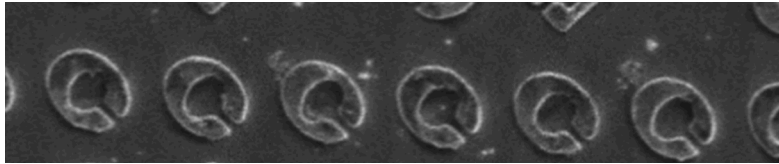
5 μ m beam



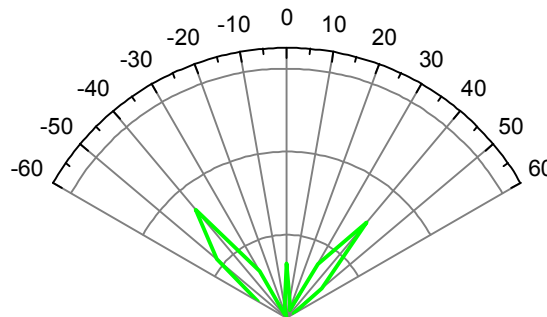
2-in-1:
Source
+beam
splitter

SHG Beam Manipulation II

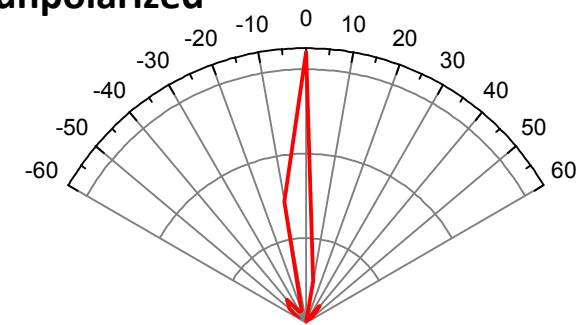
- Cavities radiate polarized light



unpolarized



v polarized



u polarized

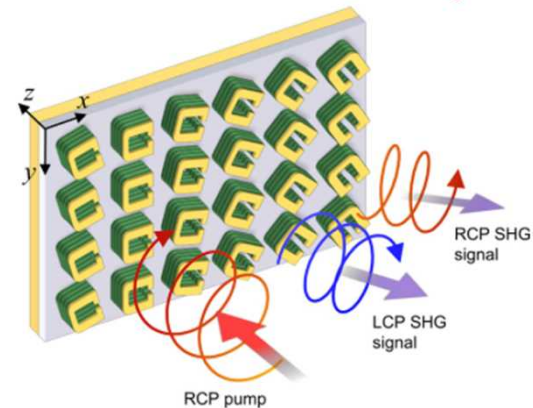


Pump
polarization

3-in-1:

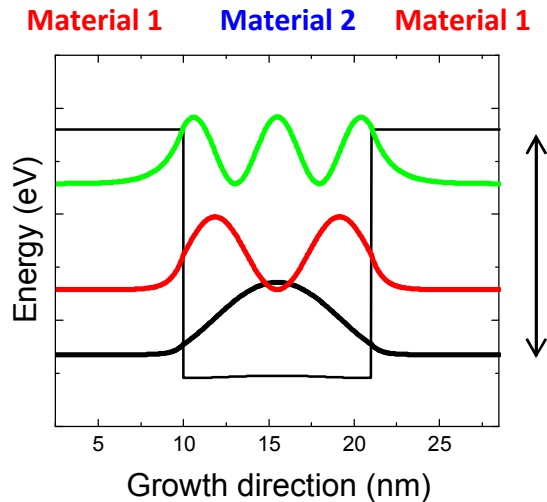
Source + Polarizer + Beam
Splitter

Belkin & Alu, PRL 2015





Scaling This Approach to Shorter Wavelengths



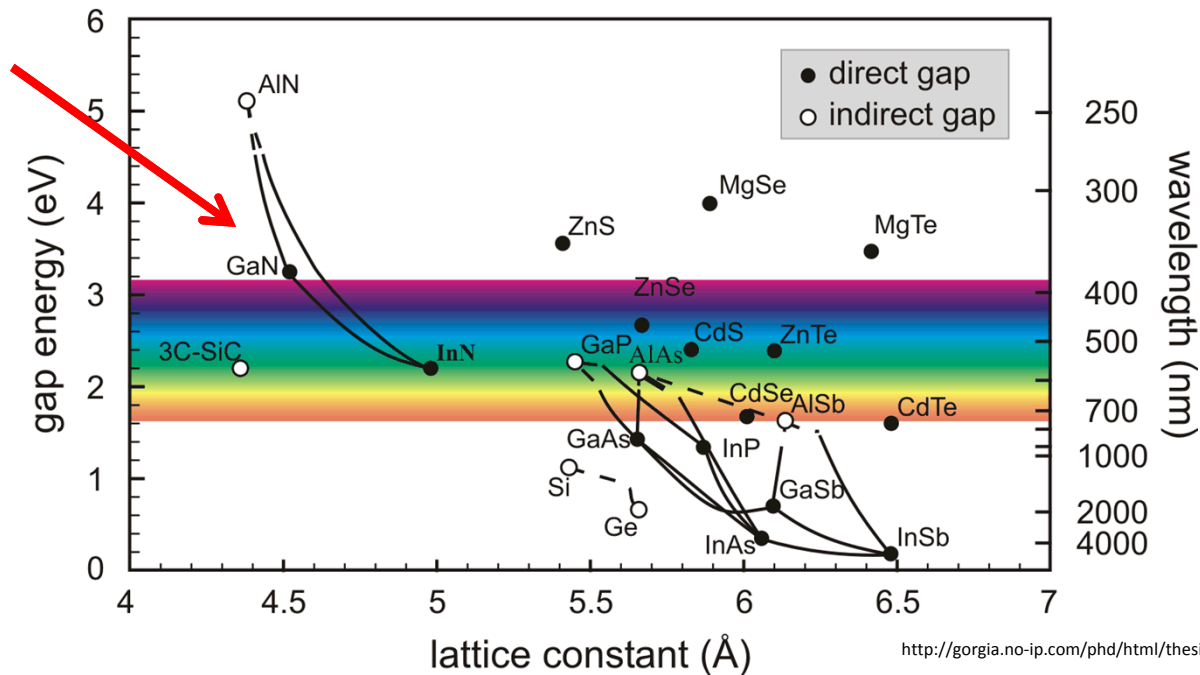
10 μ m to 5 μ m: AlInAs barriers
InGaAs wells

$$2\omega \sim 0.24\text{eV}$$

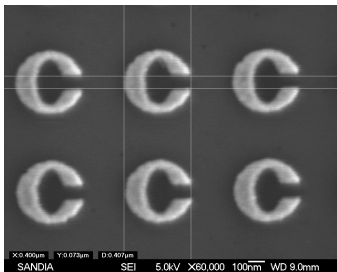
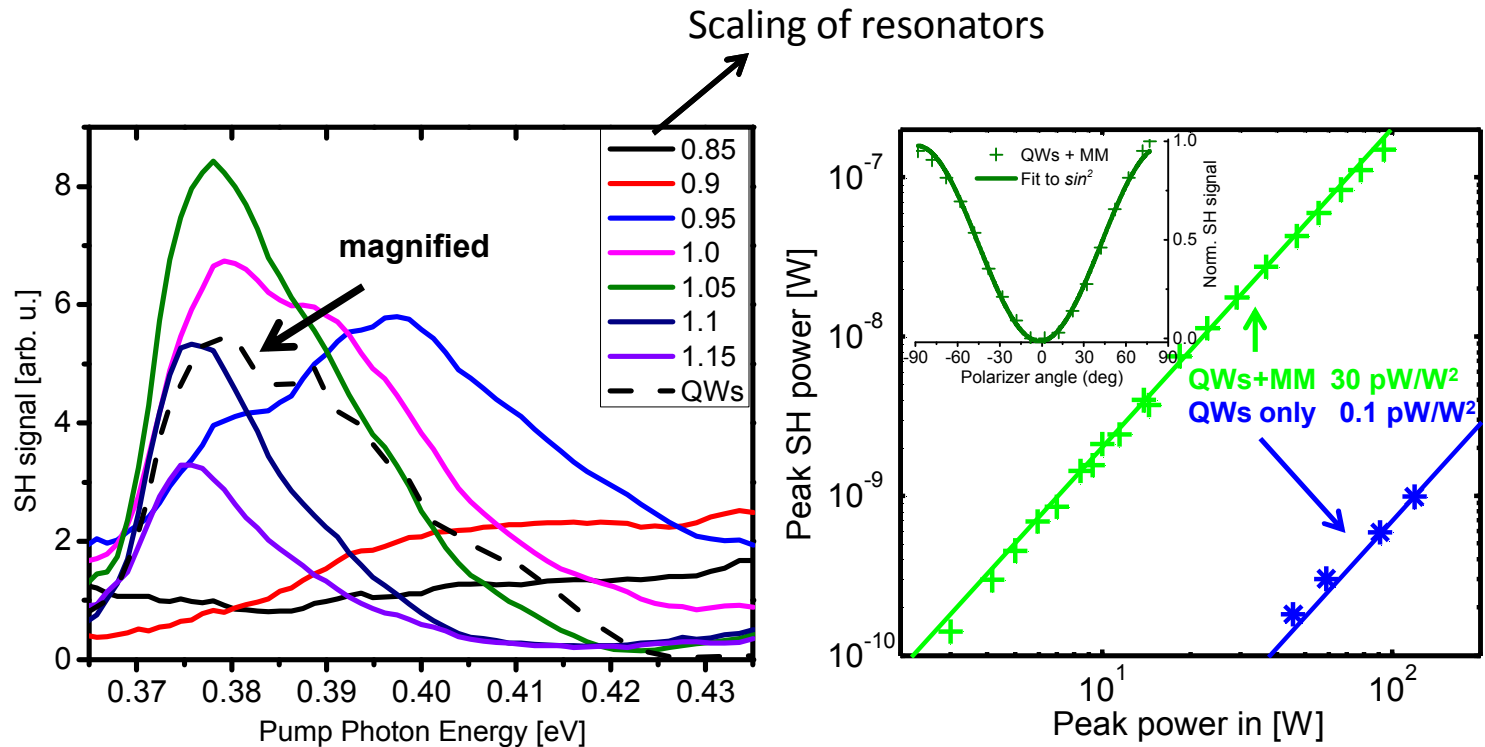
How about 1.55 μ m to 0.75 μ m?

This requires a conduction band offset of $\sim 1.6\text{eV}$!!

III-Nitrides



SHG ($3.2\mu\text{m} > 1.6\mu\text{m}$) Using AlGaIn/GaN QWs

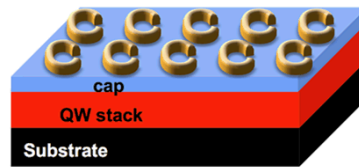


In a III-N heterostructure, metamaterials increase efficiency by over 2 orders of magnitude

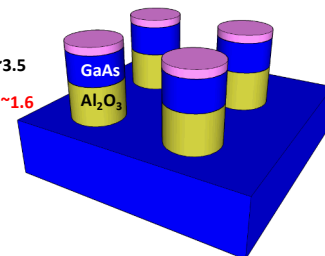
APL 107, 151108 (2015)

Outline

- Tunable Metasurfaces: overview
- Control of Strong Coupling for tunable behavior
- Harmonic generation from metallic metasurfaces coupled to intersubband transitions in semiconductor quantum wells



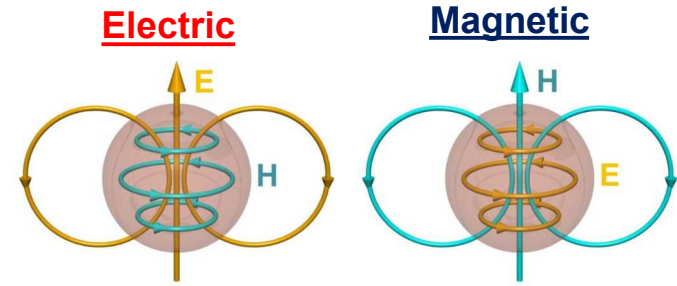
- Harmonic generation from all-dielectric metasurfaces



Dielectric Resonators for Metamaterials

Magnetic dipole resonance: tailor μ

Electric dipole resonance: tailor ϵ



Images: A. Miroshnichenko

3. Zur Optik kolloidaler Metallösungen; von R. Gans und H. Happel.

Annalen der Physik, 1909

Setzen wir (40'), (41) und (43) in die Gleichungen (44) und (45) ein, so ergibt sich die komplexe Dielektrizitätskonstante und Permeabilität der kolloidalen Lösung

$$(46) \quad \epsilon = \epsilon_0 \frac{1 + \frac{4\pi N}{3} \left(\frac{\lambda'}{2\pi} \right)^2 (a_1 - a_2)}{1 - \frac{2\pi N}{3} \left(\frac{\lambda'}{2\pi} \right)^2 (a_1 - a_2)},$$

$$(47) \quad \mu = \frac{1 - \frac{4\pi N}{3} \left(\frac{\lambda'}{2\pi} \right)^2 p_1}{1 + \frac{2\pi N}{3} \left(\frac{\lambda'}{2\pi} \right)^2 p_1}.$$

$$\epsilon'_{re} = \epsilon_{r1} \left(1 + \frac{\omega \nu_f}{\frac{F(\theta) + 2b_e}{F(\theta) - b_e} - \nu_f} \right)$$

(Ack: Ed Kuester,
CU Boulder)

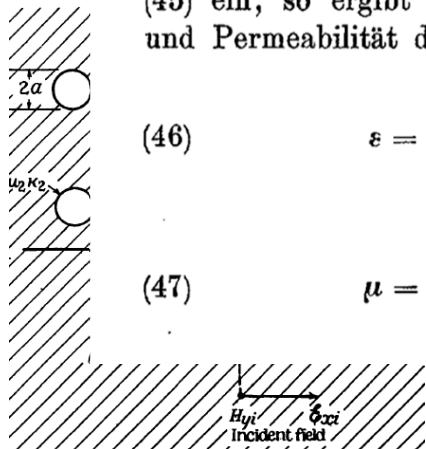
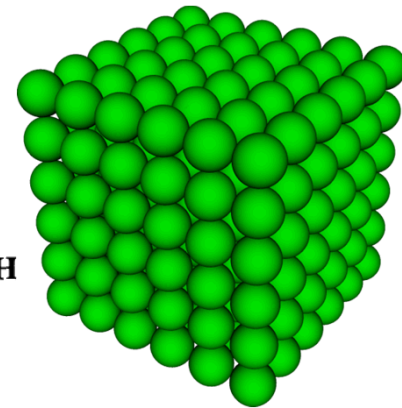
**MATERIAL LOADED WITH
ICLES***

†
red form 27th September, 1946.)

$$F(\theta) = \frac{2(\sin \theta - \theta \cos \theta)}{(\theta^2 - 1) \sin \theta + \theta \cos \theta}$$

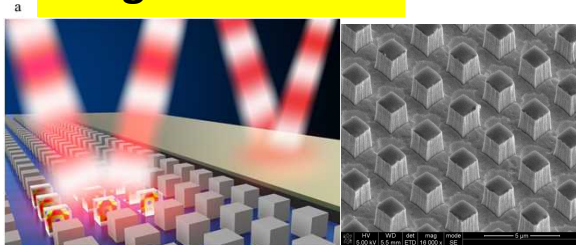
$$\theta = k_0 a \sqrt{\epsilon'_{r2} \mu'_{r2}}$$

$$b_e = \frac{\epsilon_1}{\epsilon_2}, \quad b_m = \frac{\mu_1}{\mu_2}$$



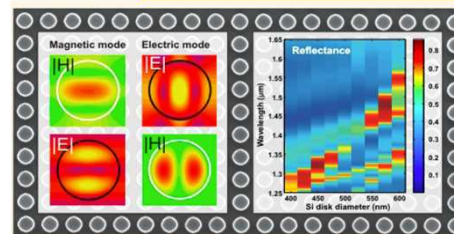
Some Recent Results with Dielectric Metasurfaces (Linear)

Magnetic mirror

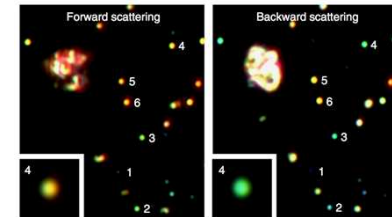


Optica 2015

Tailoring scattering

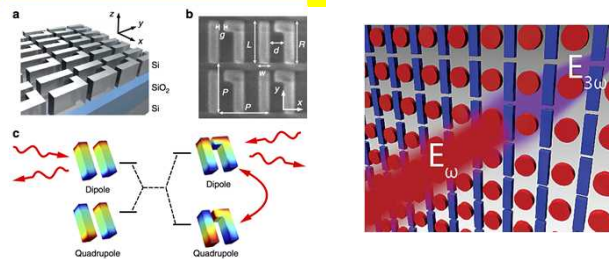


ACS Nano 7, 7824 (2013)



Nat. Comm. 4, 1527 (2013)

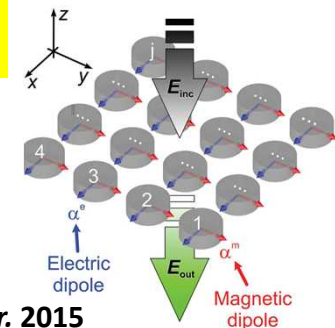
Fano resonances



Nature Comm. 2014.

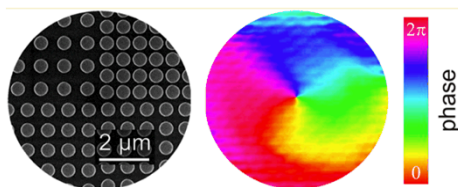
Nano Lett. 15, 7388 (2015)

Huygens Metasurfaces

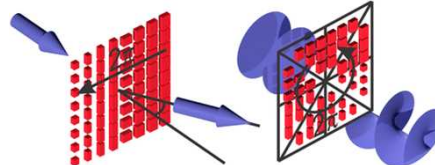


Adv. Optical Mater. 2015

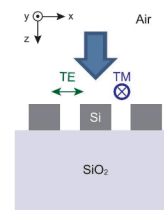
Phase-front manipulation



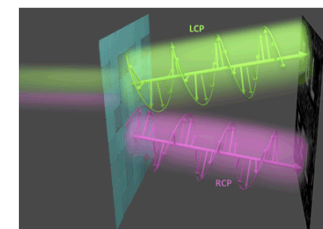
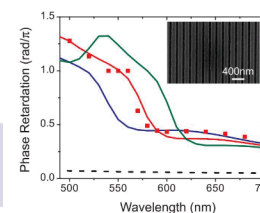
Nano Lett. 15, 5369 (2015)



Nano Lett. 15, 6261 (2015)

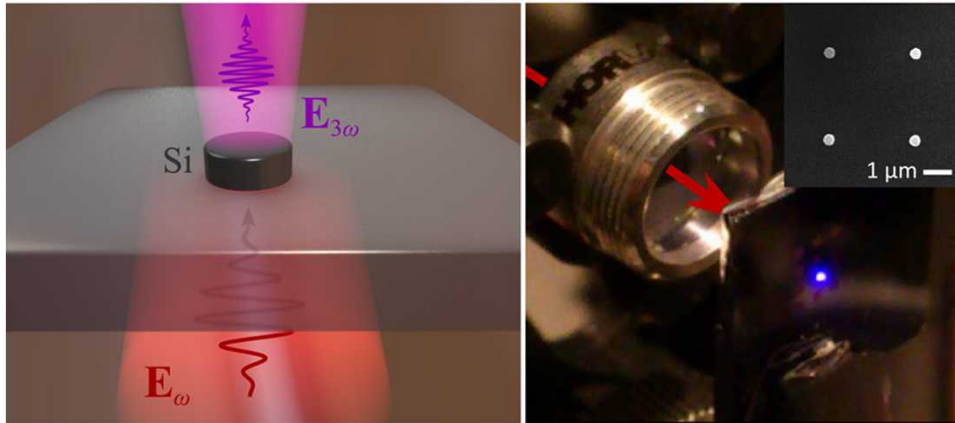


Science 345, 2015



Opt. Express 23, 22611 (2015)

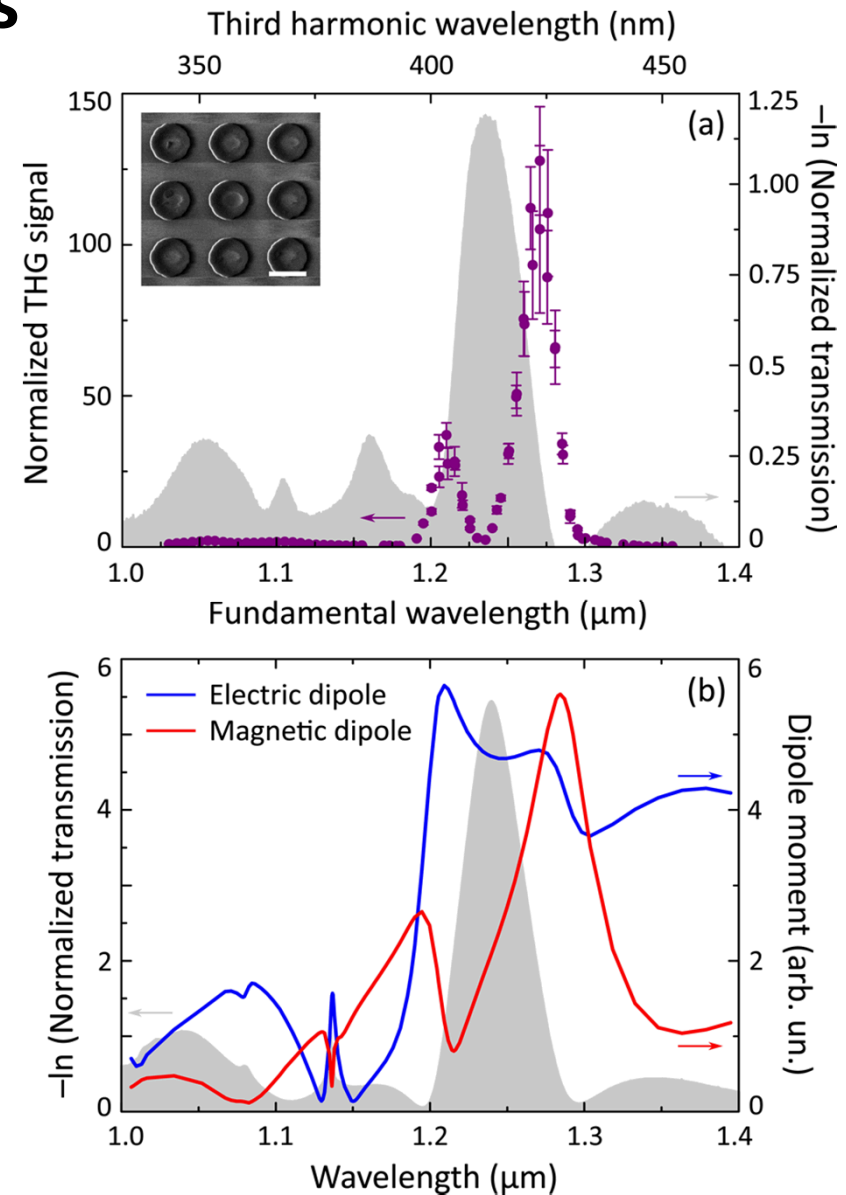
Optical Nonlinearities (THG) in Si Dielectric Metasurfaces



Strong enhancement near magnetic dipole resonance

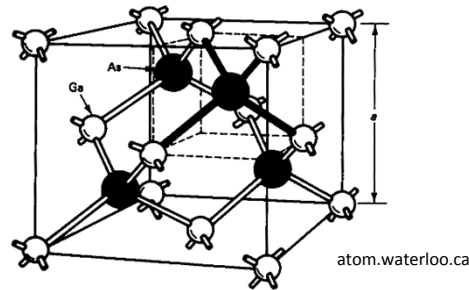
(With ANU & Moscow State
Maxim R. Shcherbakov, Alexander S. Shorokhov, Dragomir N. Neshev, Ben Hopkins, Isabelle Staude, Elizaveta V. Melik-Gaykazyan, Alexander A. Ezhov, Andrey E. Miroshnichenko, Igal Brener, Andrey A. Fedyanin, and Yuri S. Kivshar)

Nano Letters (2015)

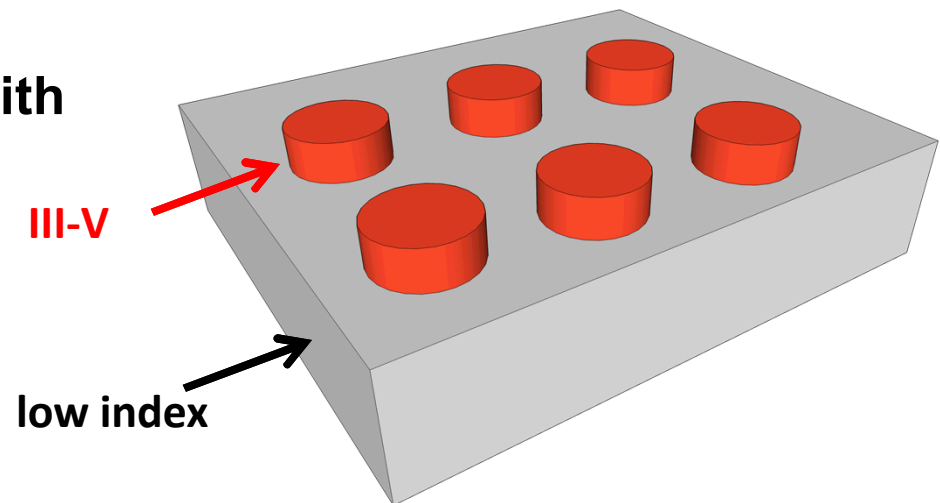


Silicon is “limited” for Optical Nonlinearities

- Silicon is centrosymmetric → NO second order nonlinearity
- Lots of III-V semiconductors have $\chi^{(2)}$
- Example, GaAs:

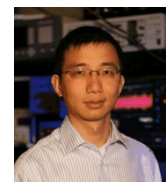


How to obtain high index dielectric nanoresonators with III-V semiconductors??

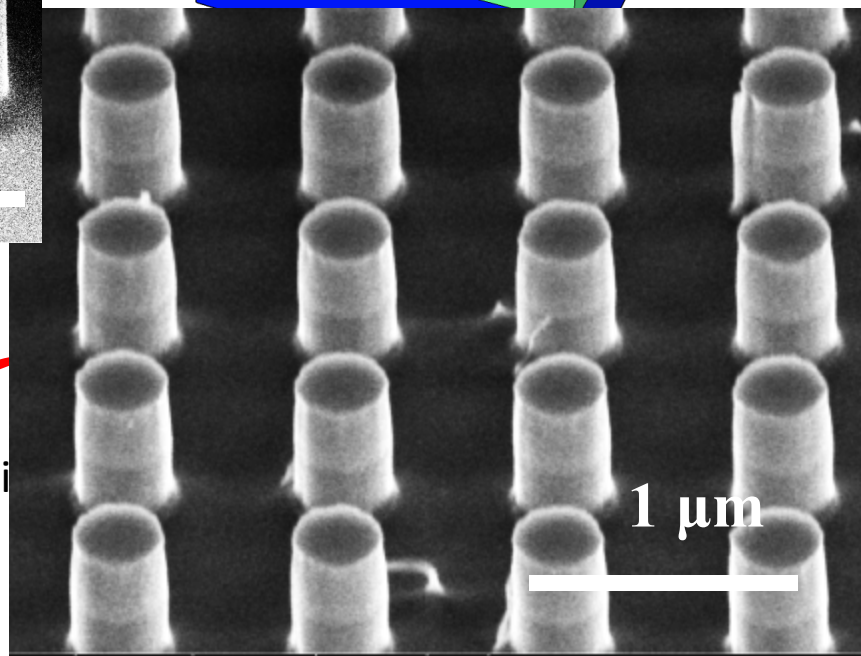
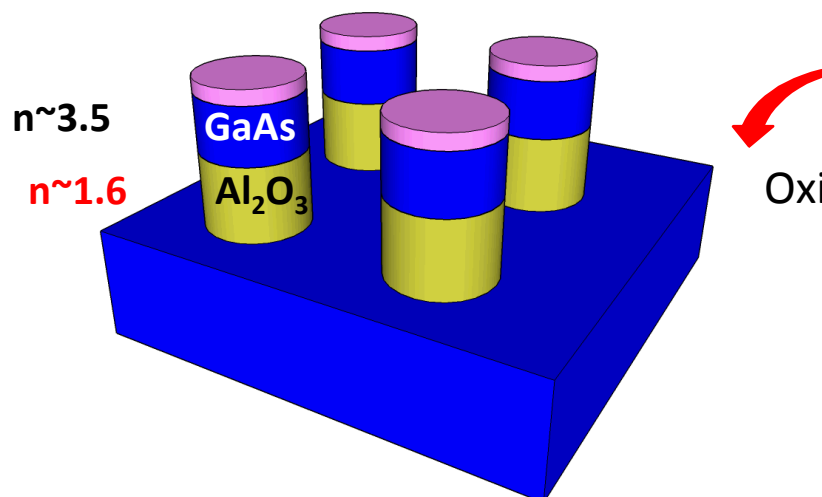
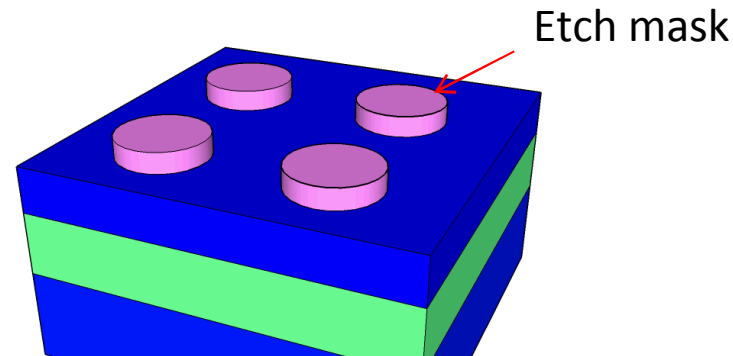
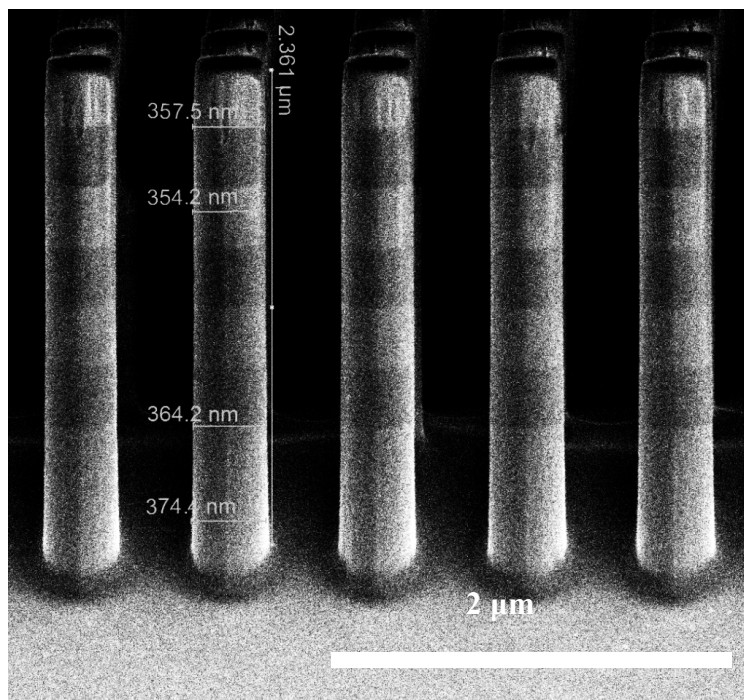




Fabrication of Al(In)GaAs Based Dielectric MMs



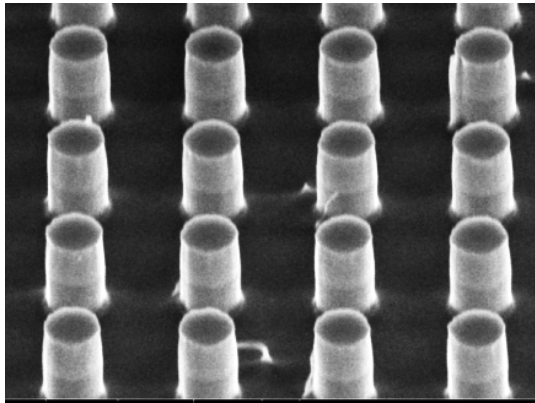
Sheng Liu



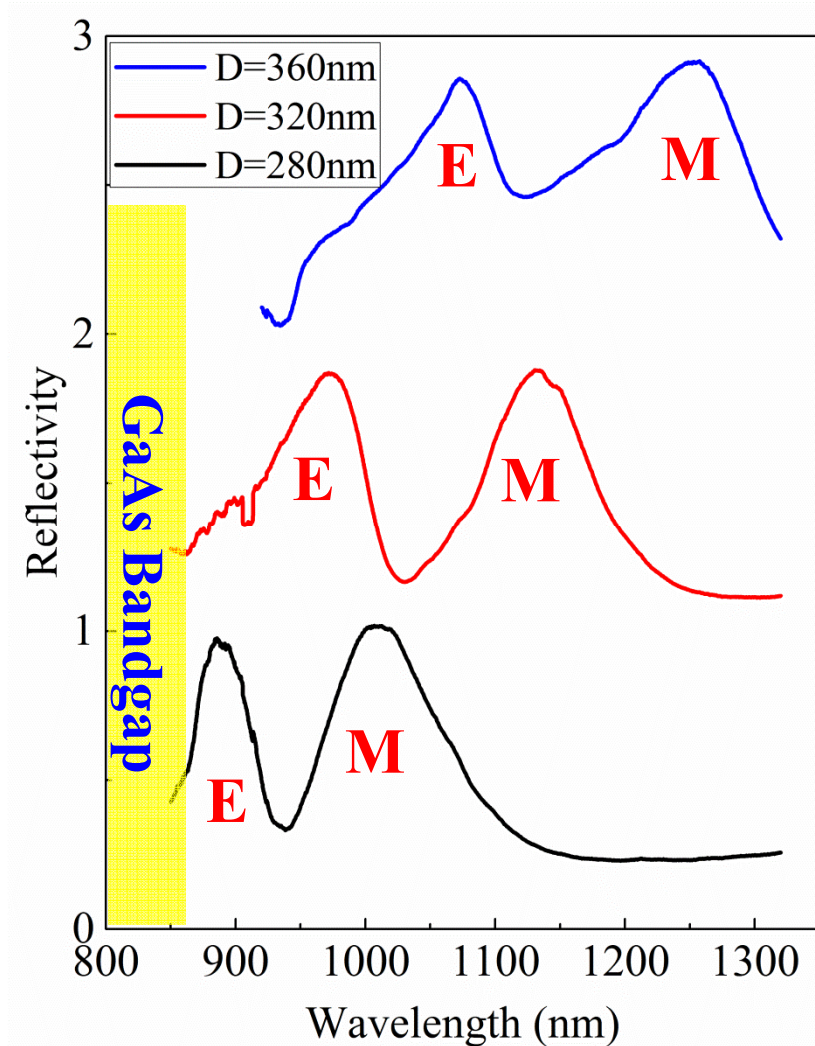
GaAs Dielectric Resonators (1 layer)

GaAs disk height $\sim 300\text{nm}$

Different diameters

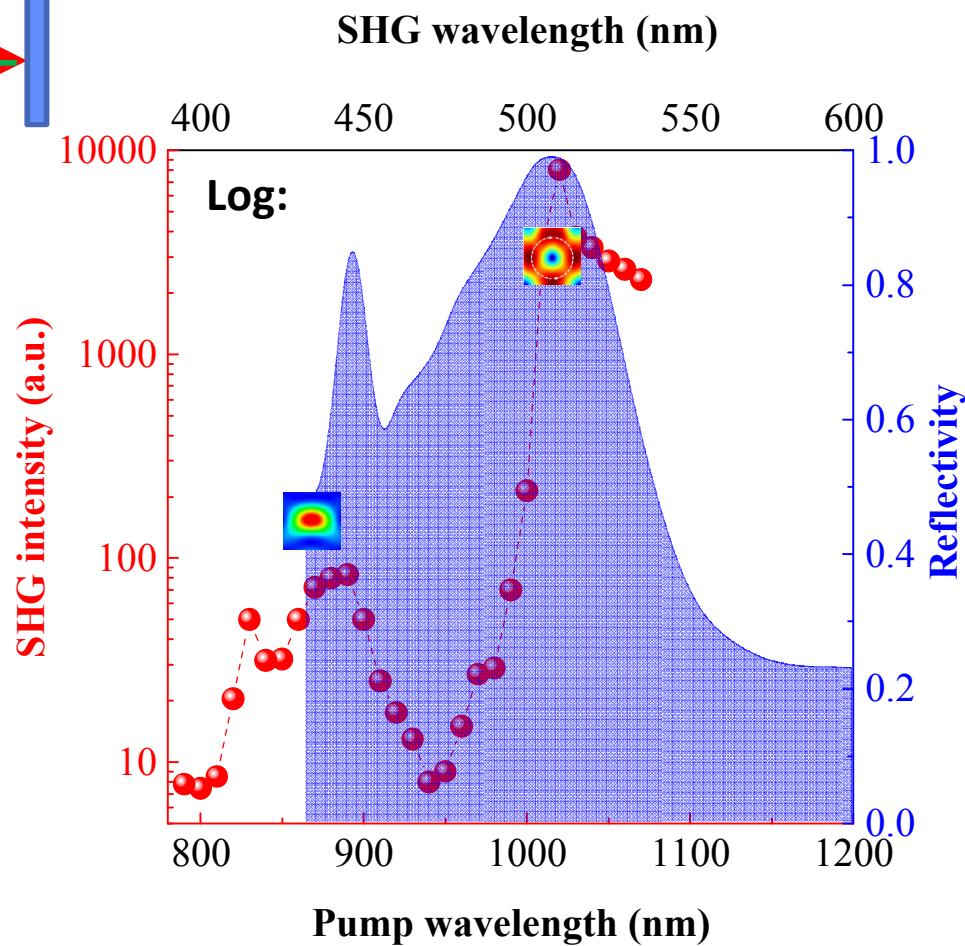
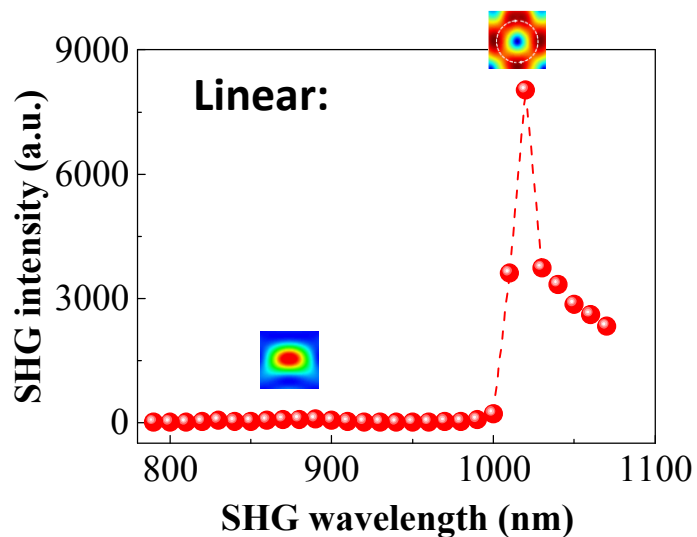
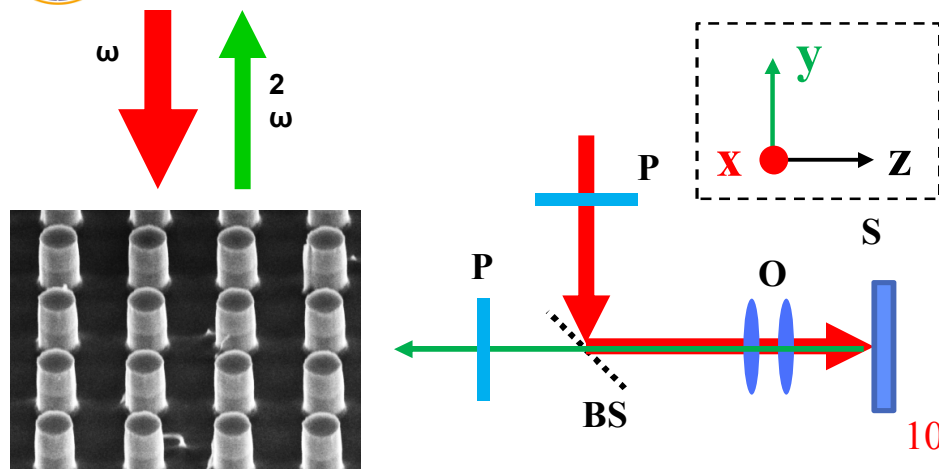


- Extremely low loss below bandgap
- Crystalline





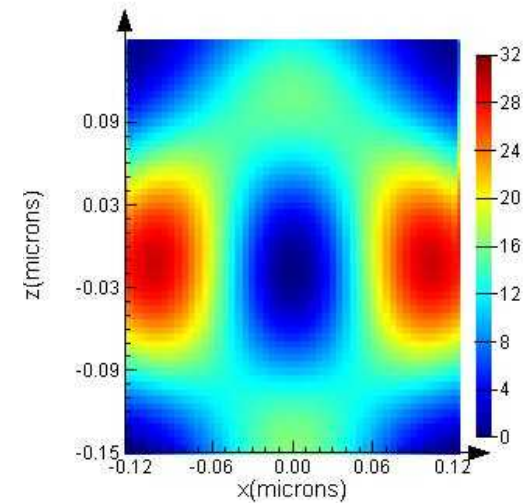
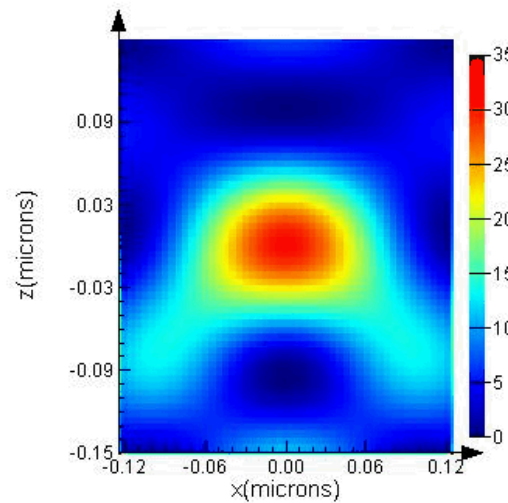
Second Harmonic spectral dependence



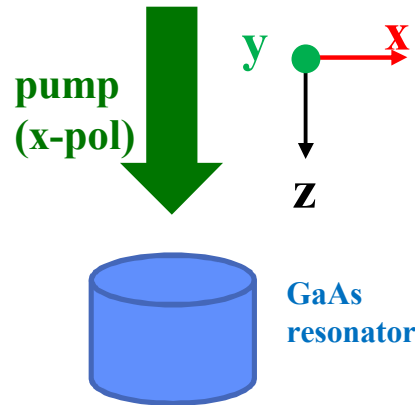
Polarization, Selection Rules

$|E|^2$ enhancement for both electric and magnetic dipole resonance.

($I_{2\omega}$ proportional to I_{ω}^2)

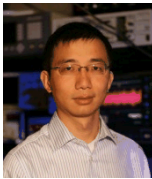


There are only E_x and E_z component inside the GaAs resonators.



$$E_y^{2\omega} = 2\chi_{xxy}^{(2)} E_x^{\omega} E_z^{\omega}$$

Orthogonal SHG polarization compared to the pump is expected



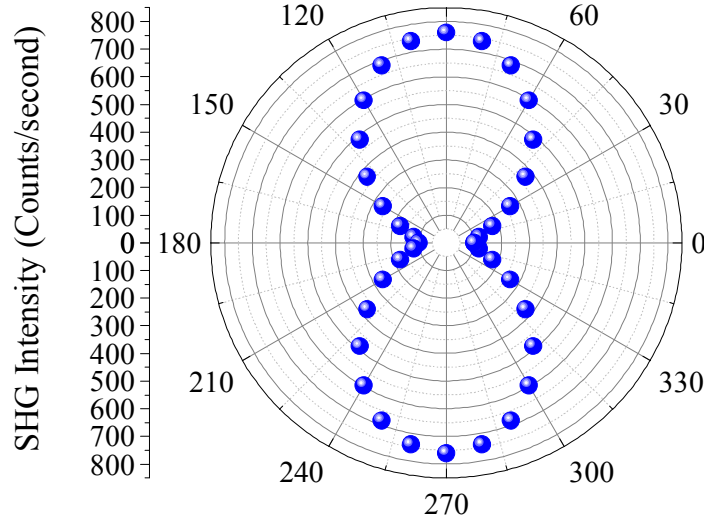
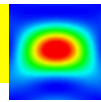
Sheng Liu



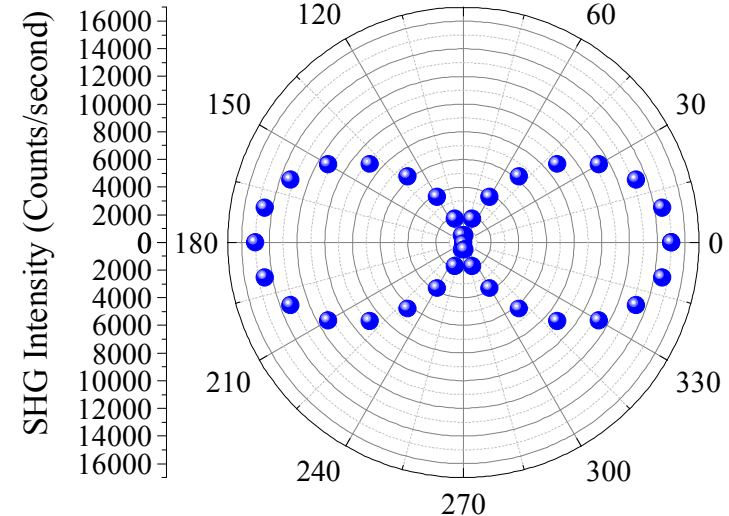
Pump



E-dipole resonance



M-dipole resonance



This is not consistent with bulk $\chi^{(2)}$

What happens at the M-dipole resonance?

1. Surface nonlinearity changes symmetry to mm2

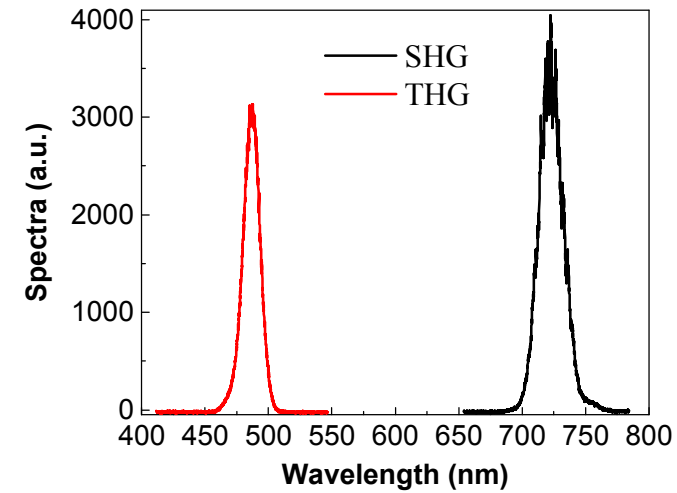
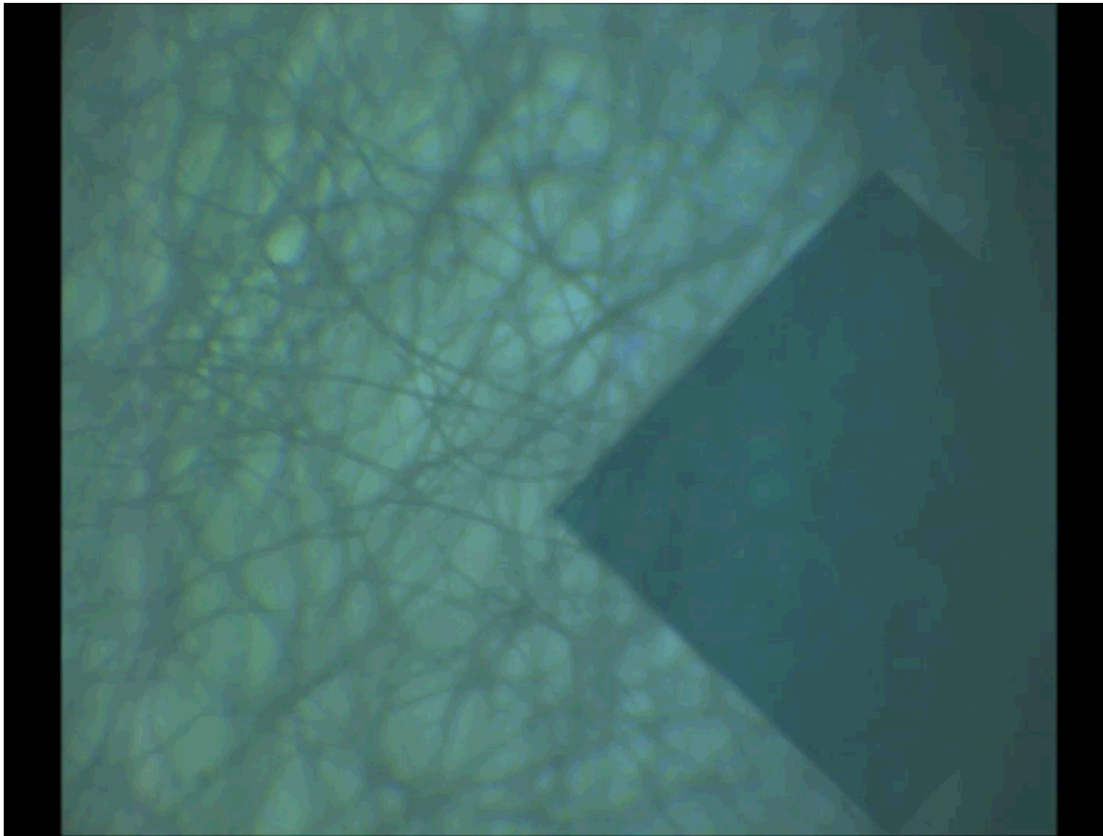
$$E_x^{2\omega} = 2\chi_{xxz}^{(2)} E_x^\omega E_z^\omega$$

can be large, considering the large field enhancement at the surface for this mode.

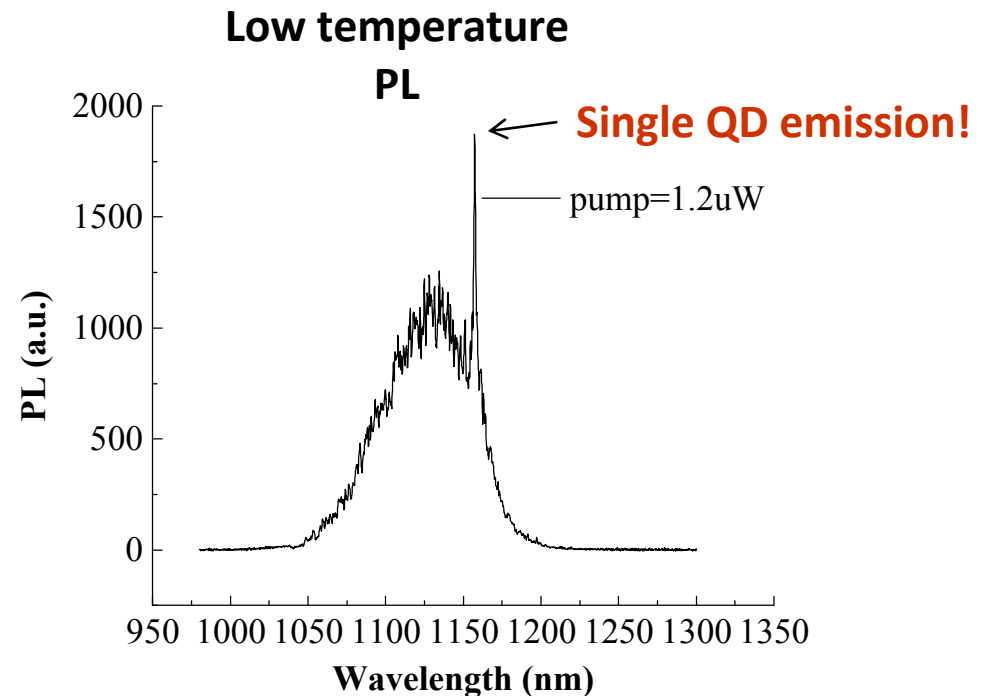
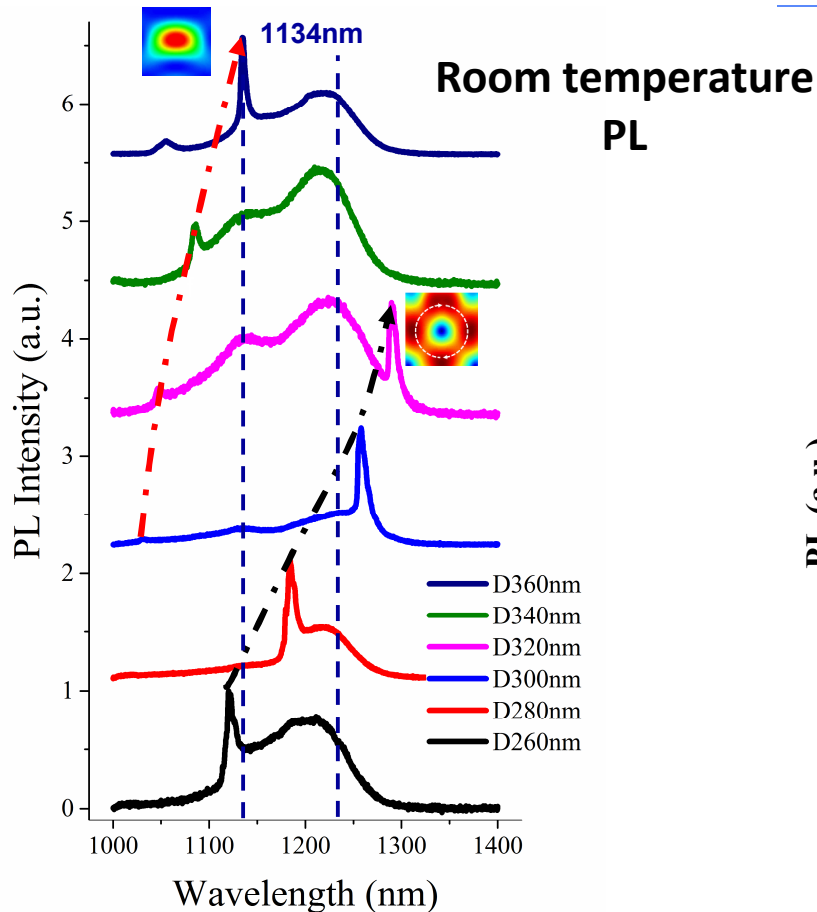
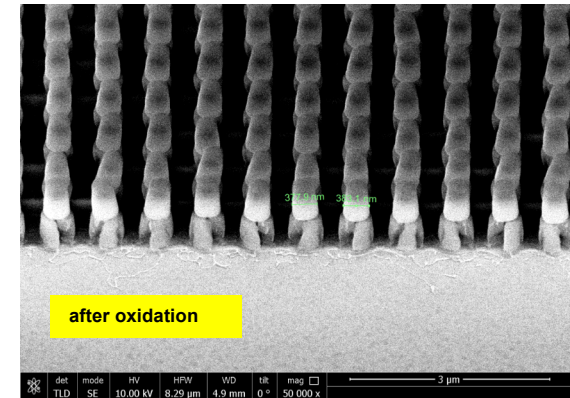
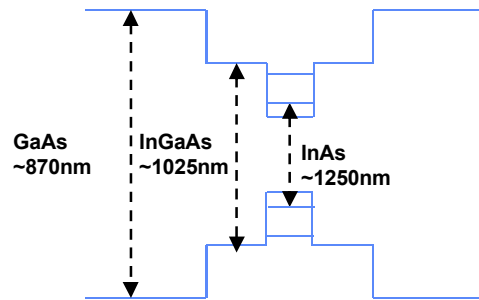
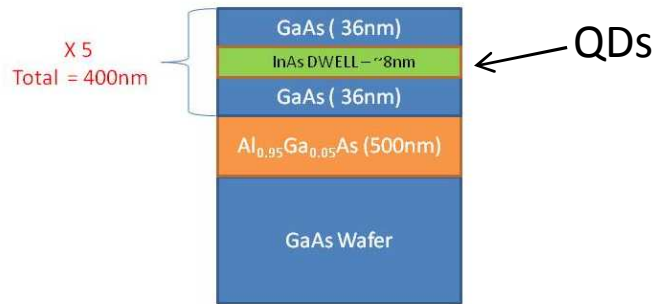
2. SHG is above bandgap of GaAs, absorption favors SHG generated at the surface.

Not predicted: Carletti *et al.*, "Enhanced second-harmonic generation from magnetic resonance in AlGaAs nanoantennas", *Optics Express*, 23, 26544 (2015)

Simultaneous SHG & THG....



“Active” All-Dielectric Metasurfaces





Summary & Acknowledgments

- Tunable Metasurfaces: overview
- Control of Strong Coupling for tunable behavior
- Harmonic generation from metallic metasurfaces coupled to intersubband transitions in semiconductor quantum wells
- Harmonic generation from all-dielectric metasurfaces

Departed postdocs: Young-Chul Jun, Alex Benz, Alon Gabbay

Current postdocs: Salvo Campione, Omri Wolf, Sheng Liu

CINT + Sandia:  Mike Sinclair, Ines Montano,  Eric Shaner, Mike Wanke, Joel Wendt, Paul Clem, Jon Ihlefeld, Bruce Burckel, Jason Dominguez,  Sally Samora, Jon Wierer,
 **GaAs**  **InGaAs**
 **GaN**

I. d'Optique: Francois Marquier, Jean-Jacques Greffet

UNM: Ganesh Balakrishnan (QD samples)



U.S. DEPARTMENT OF
ENERGY

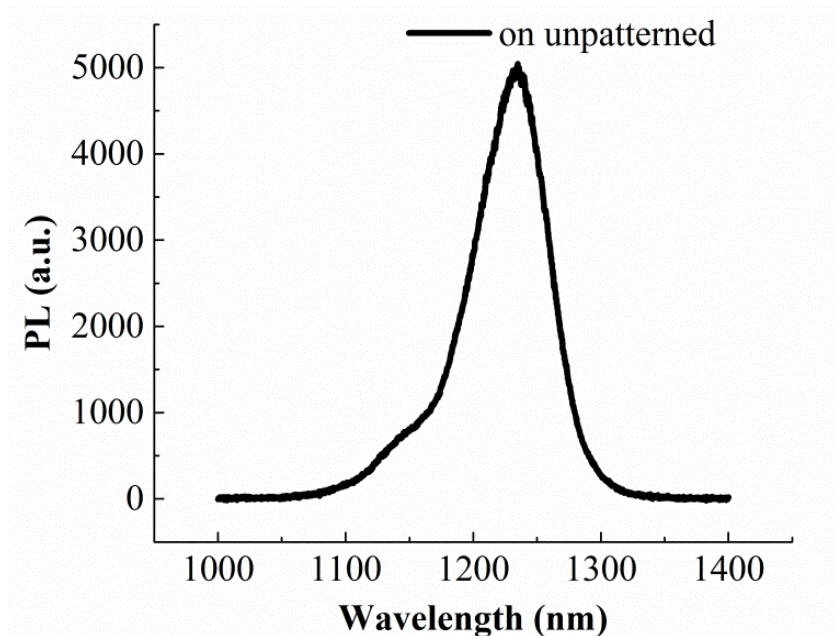
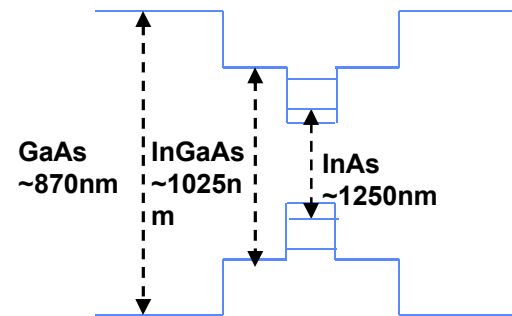
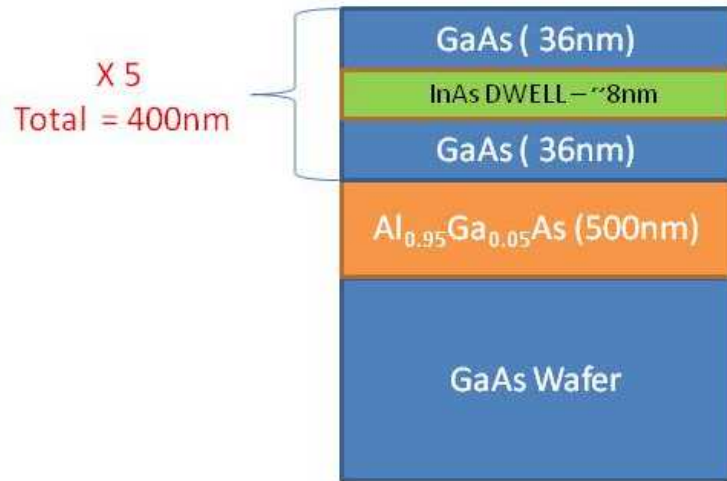
Office of
Science



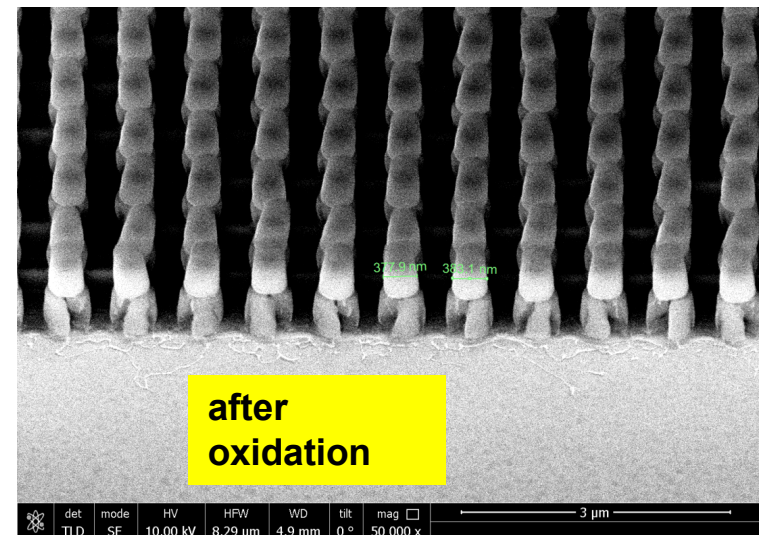
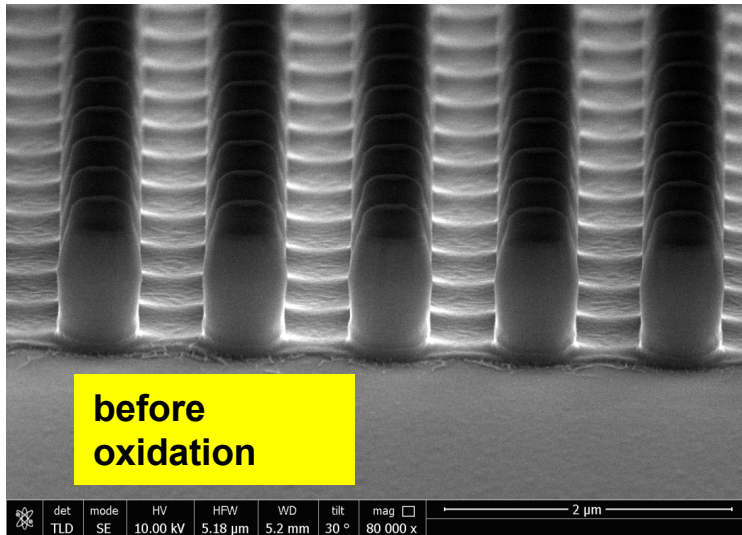
Outline

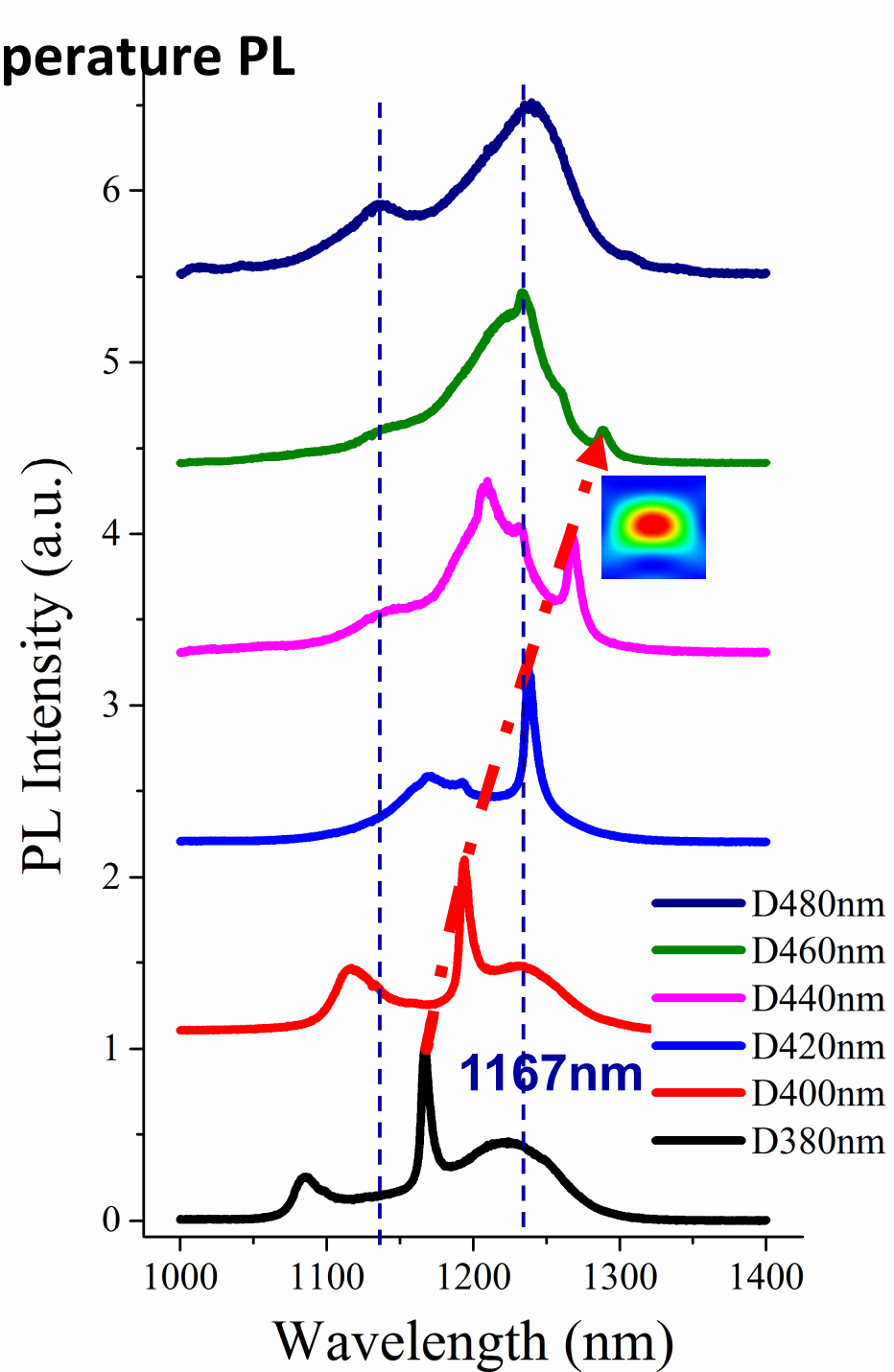
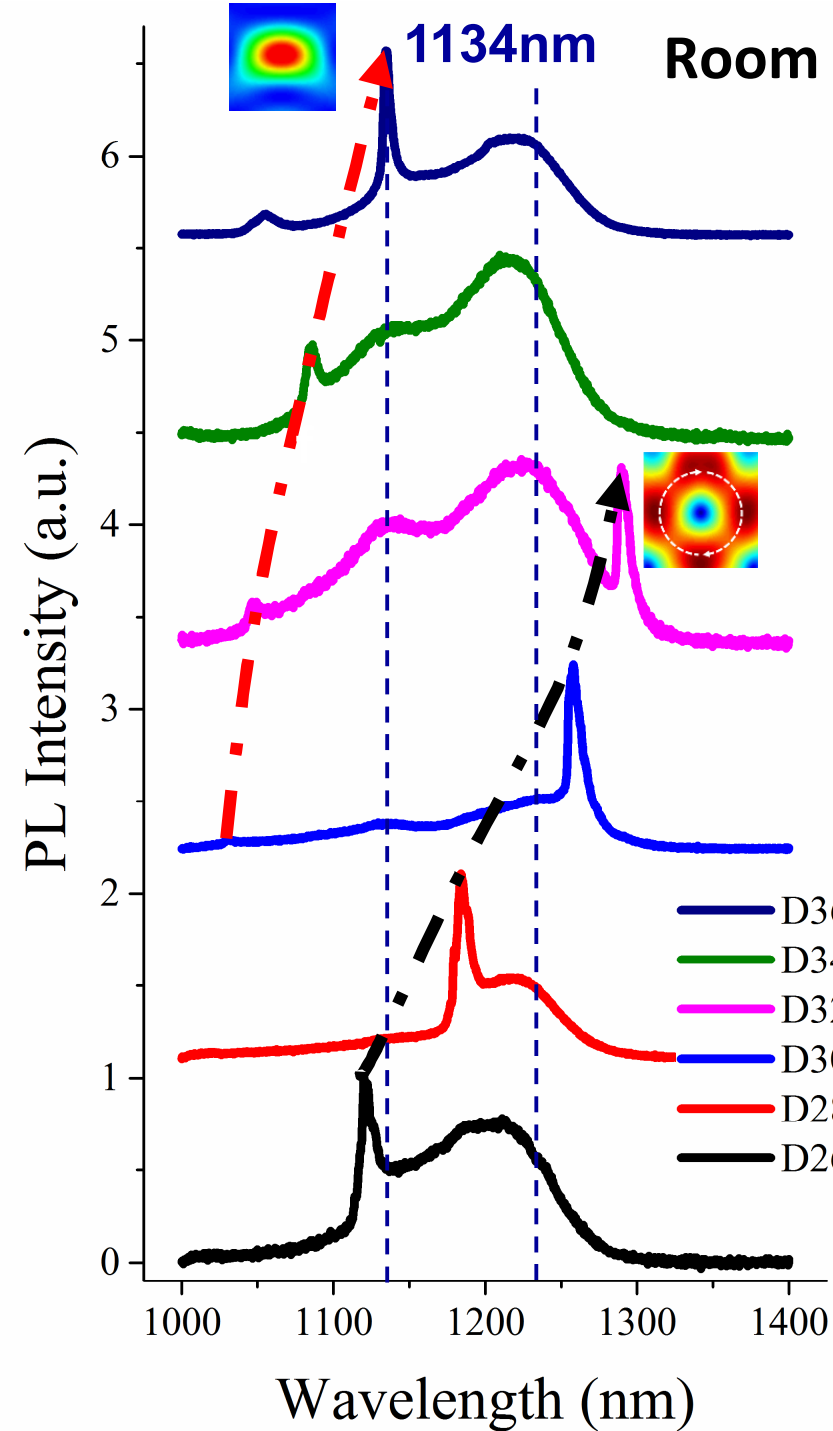
- Record optical nonlinearities in the infrared obtained from metallic metasurfaces coupled to intersubband transitions
- Progress in second harmonic generation from III-V semiconductor dielectric metasurfaces
- New Fano designs for all-dielectric metasurfaces
- **Coupling of epitaxial quantum dot emitters to dielectric resonators**

Active III-V Dielectric Resonators

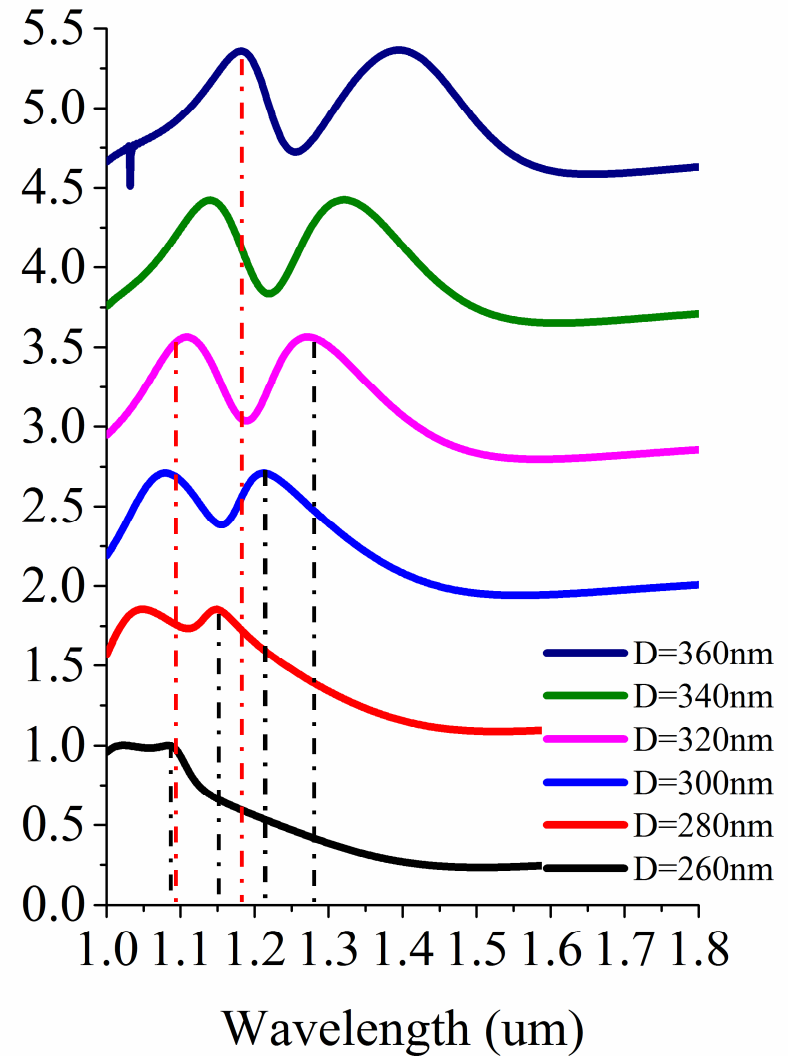
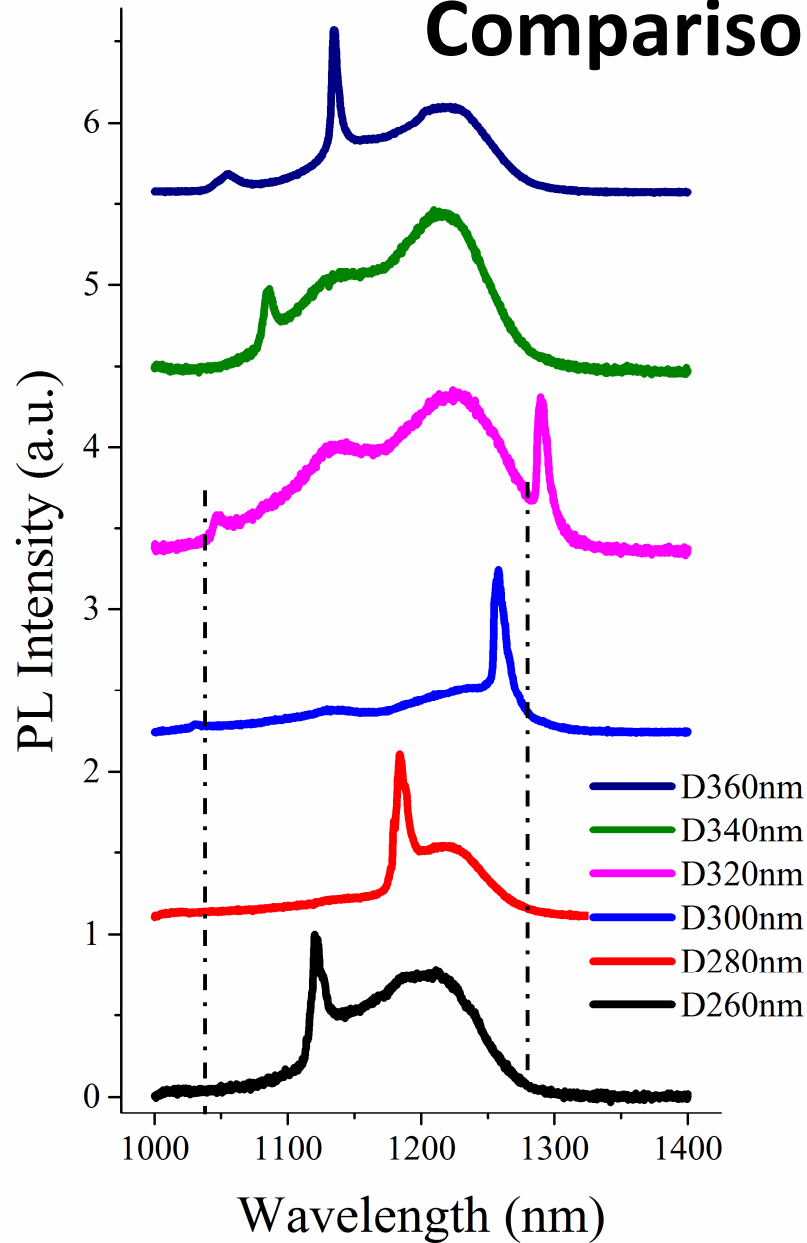


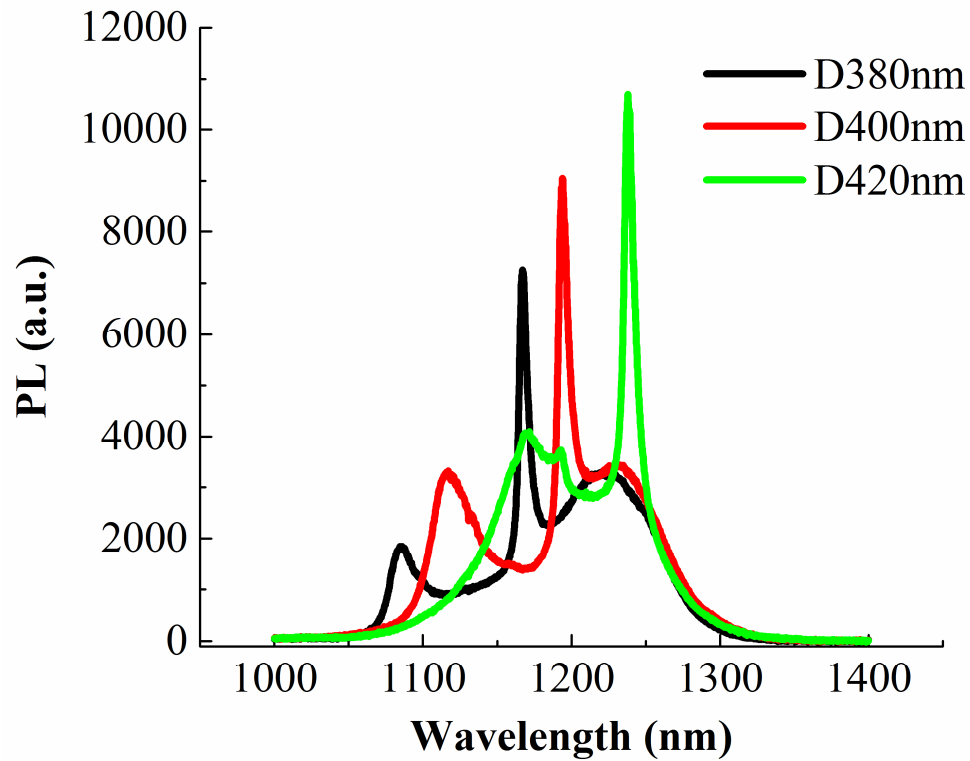
Fabrication





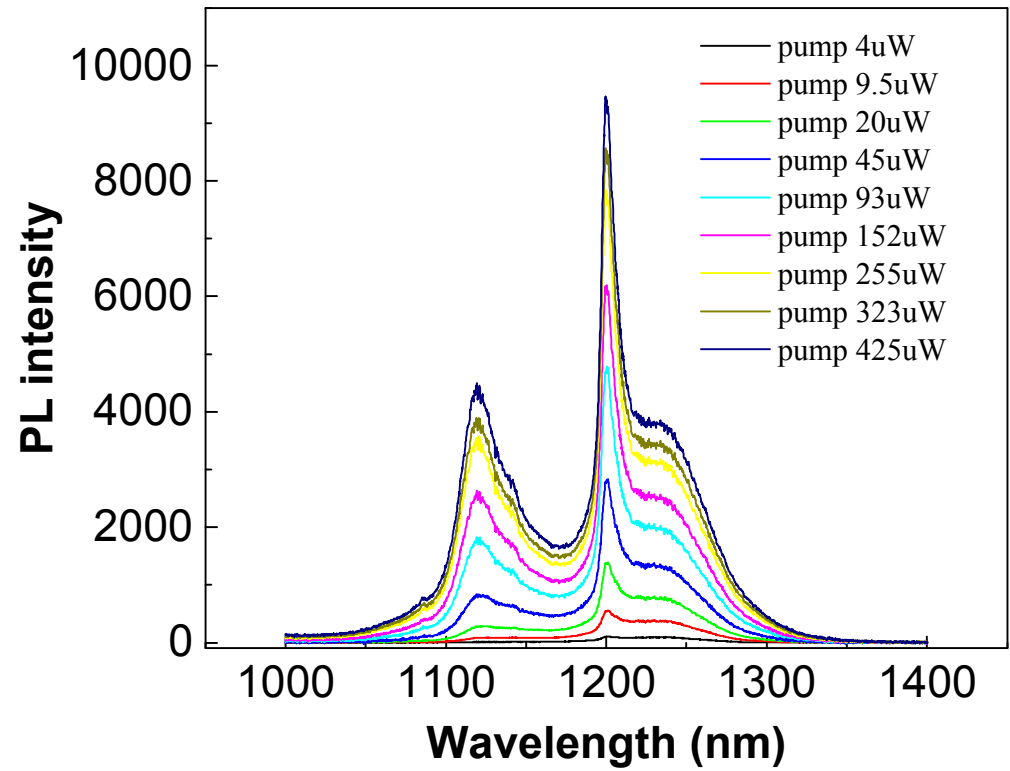
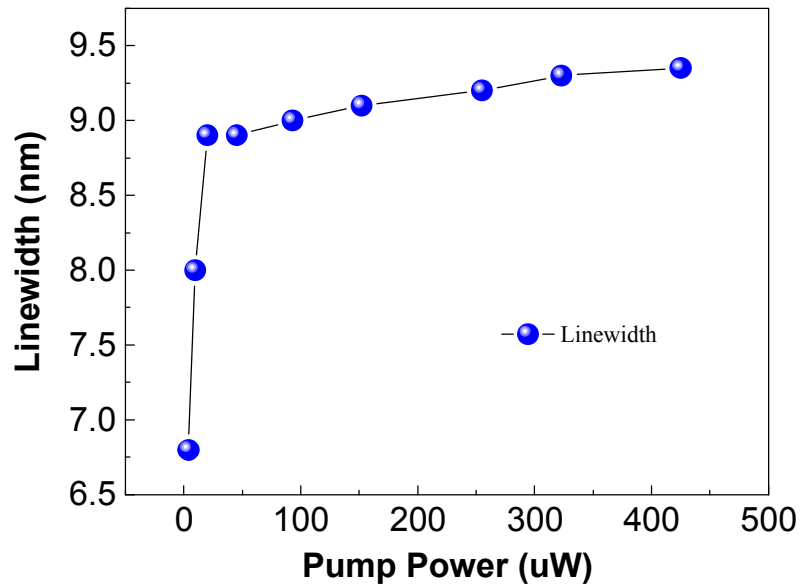
Comparison to FDTD Modeling





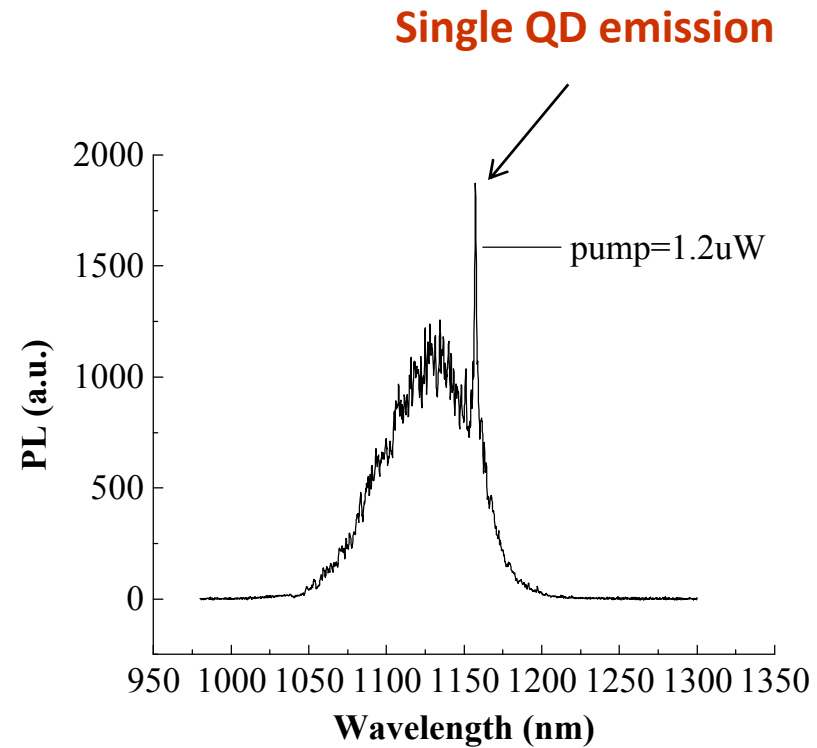
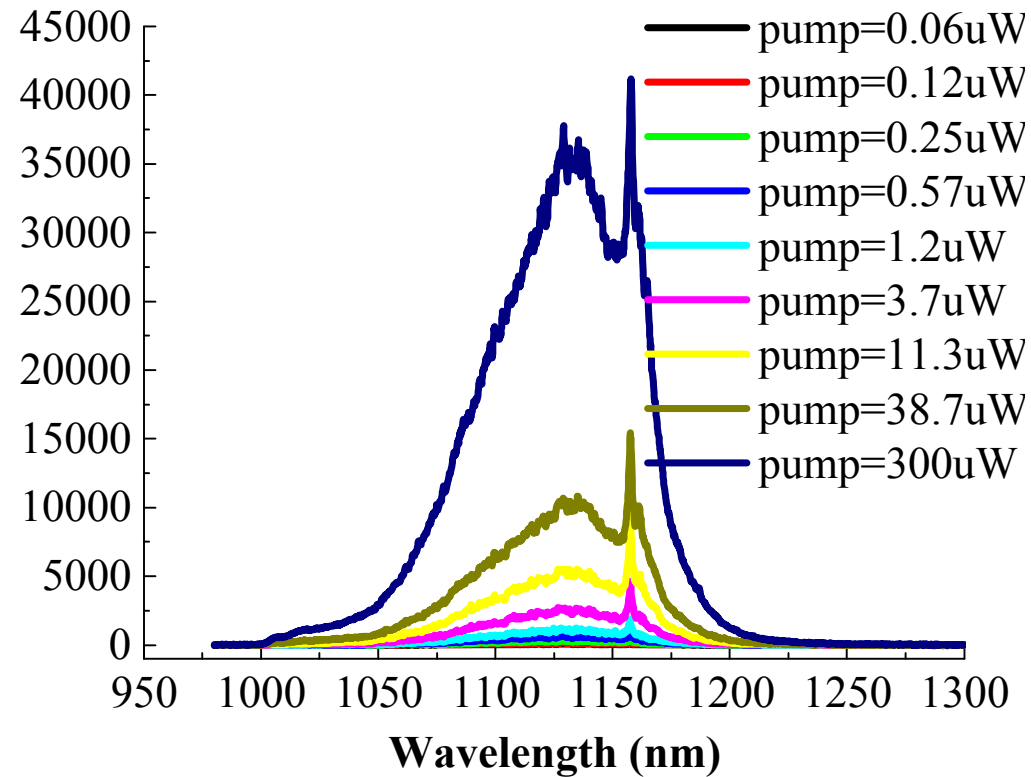
The PL intensity enhancement is **larger** at electric dipole resonance than at the magnetic dipole resonance.

This is not Lasing!



T=8K Results

At low powers it is quite easy to see
very narrow peaks

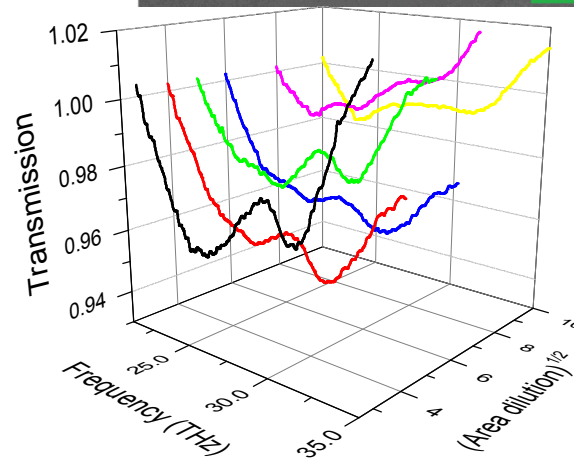
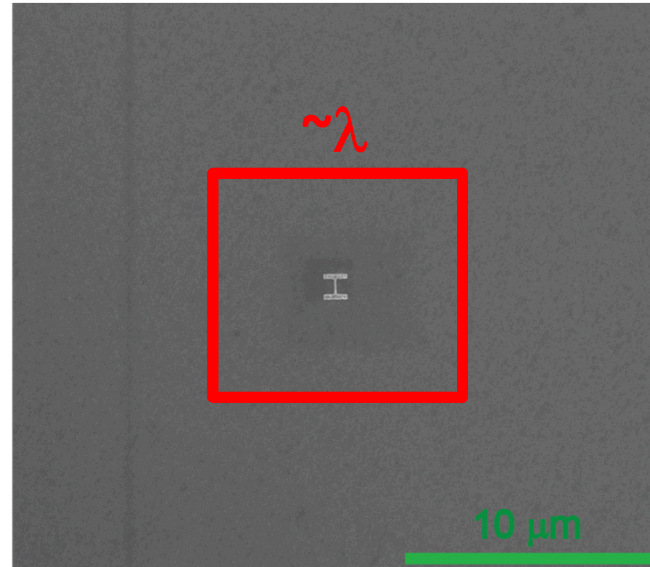
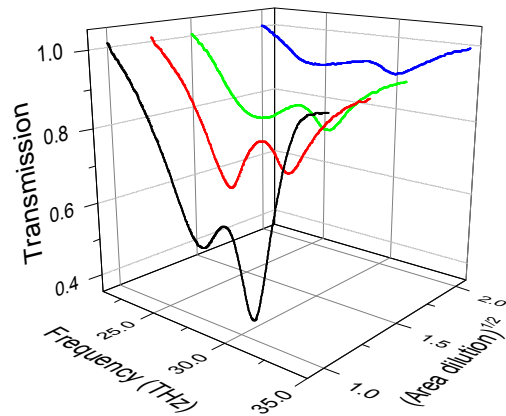
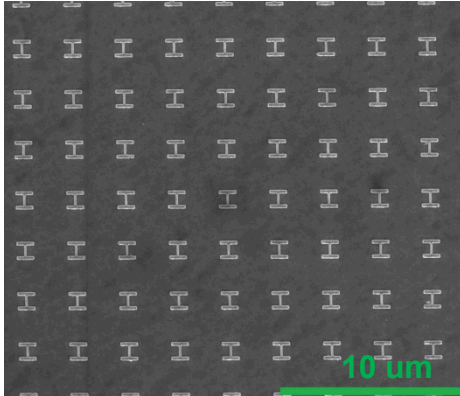




Outline

- Record optical nonlinearities in the infrared obtained from metallic metasurfaces coupled to intersubband transitions
- **Progress in second harmonic generation from III-V semiconductor dielectric metasurfaces**
- New Fano designs for all-dielectric metasurfaces
- Coupling of epitaxial quantum dot emitters to dielectric resonators

This is a “Single Resonator” Behavior



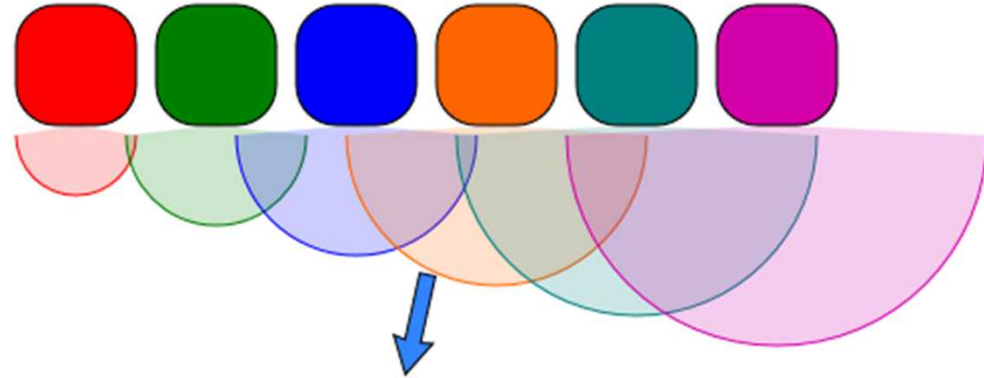
Same Rabi splitting remains down to a single resonator!

Nature communications **4**, (2013)

Area of a resonator * carrier density ~1000-3000 electrons!



Phased Arrays



Identical point sources

+

Radiating with controllable phase difference

==

Full control over beam direction and shape

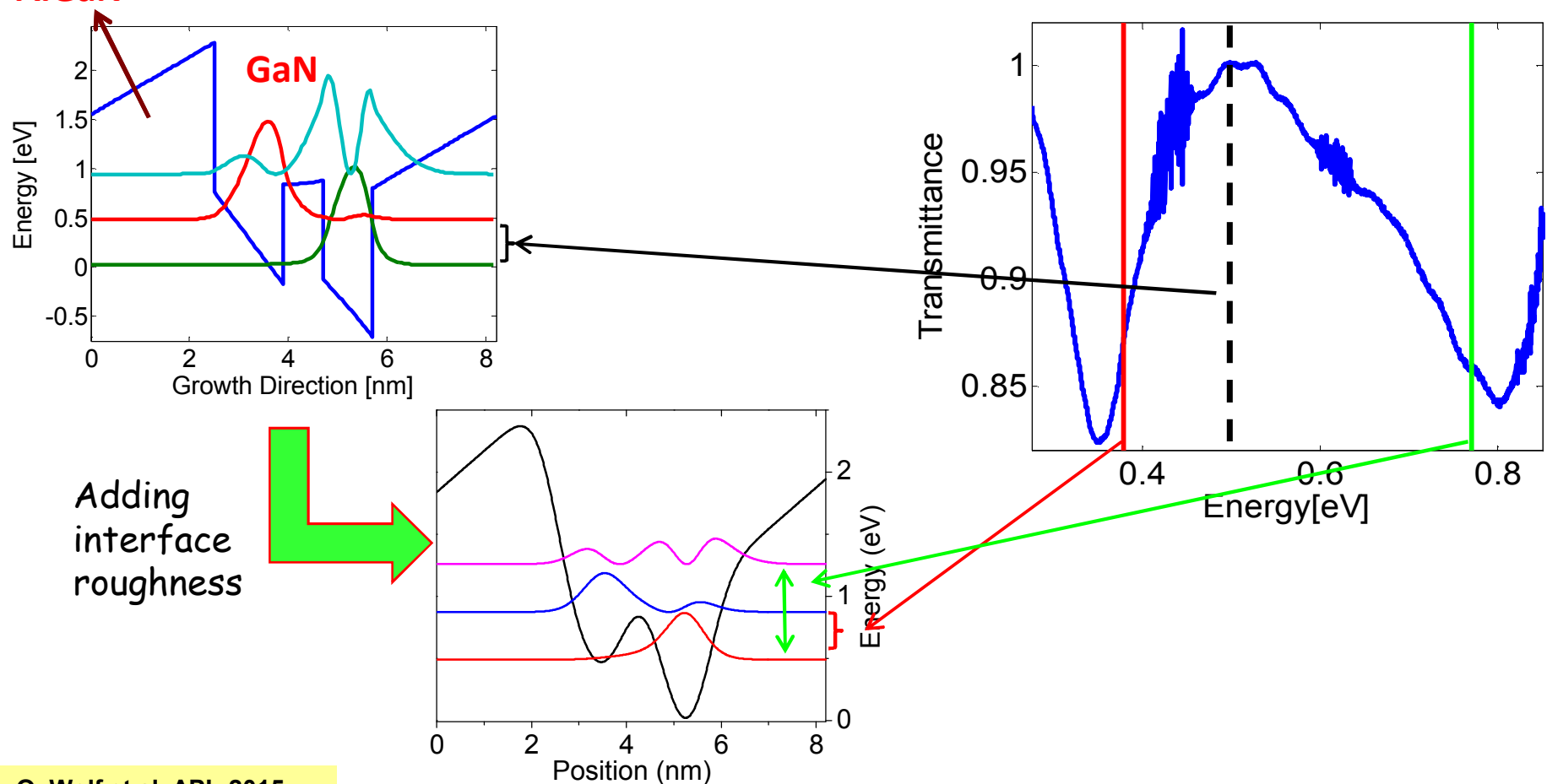


Omri Wolf

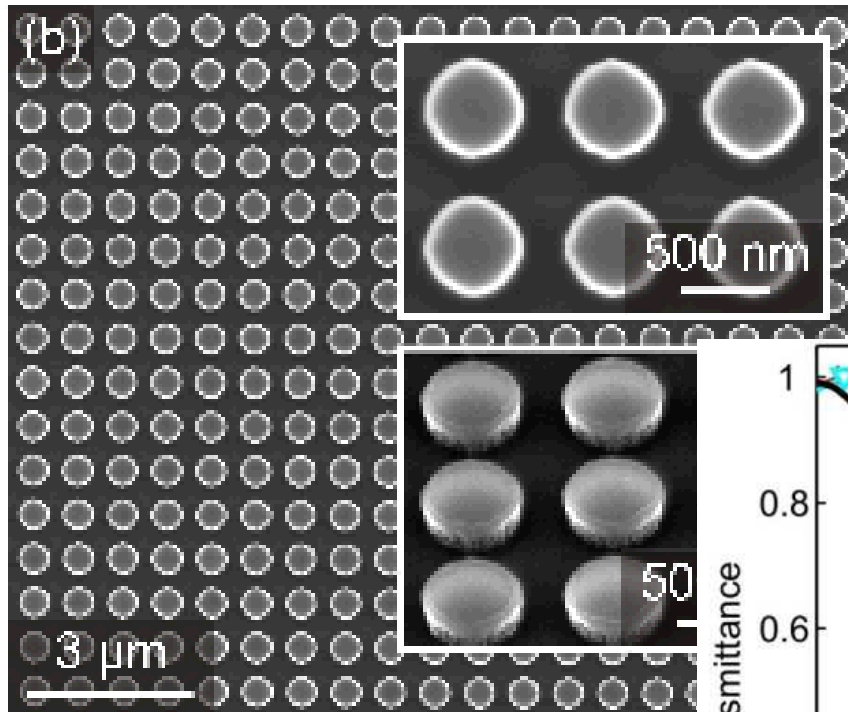
SHG ($3.2\mu\text{m} \rightarrow 1.6\mu\text{m}$) Using AlGaN/GaN QWs

- Design: SHG $3\mu\text{m} \rightarrow 1.5\mu\text{m}$ ($0.4\text{ eV} \rightarrow 0.8\text{ eV}$)
- Traditional band structure calculation not enough

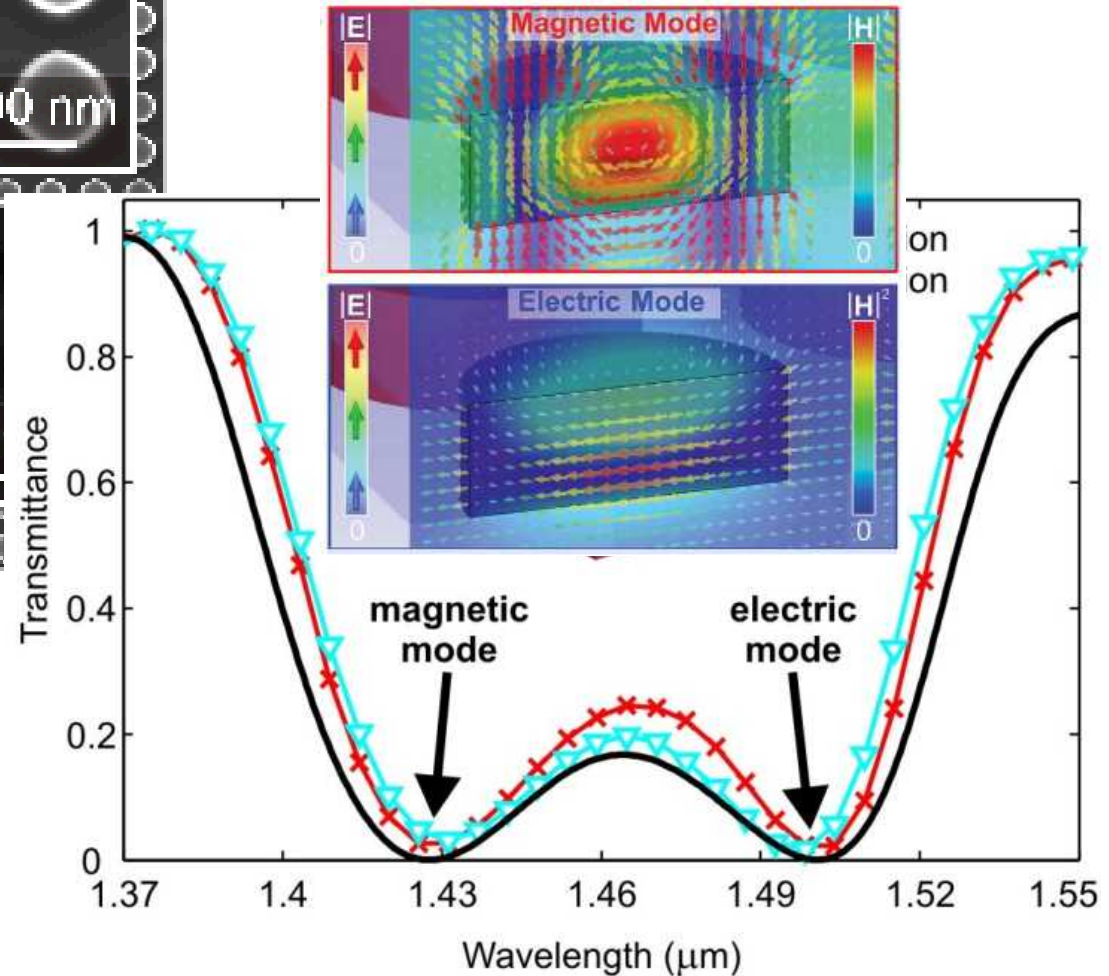
AlGaN – Over estimation of IST



LC tunable dielectric MSs

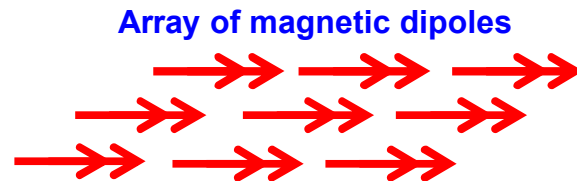


**EBL and dry etching
on Sol wafer**



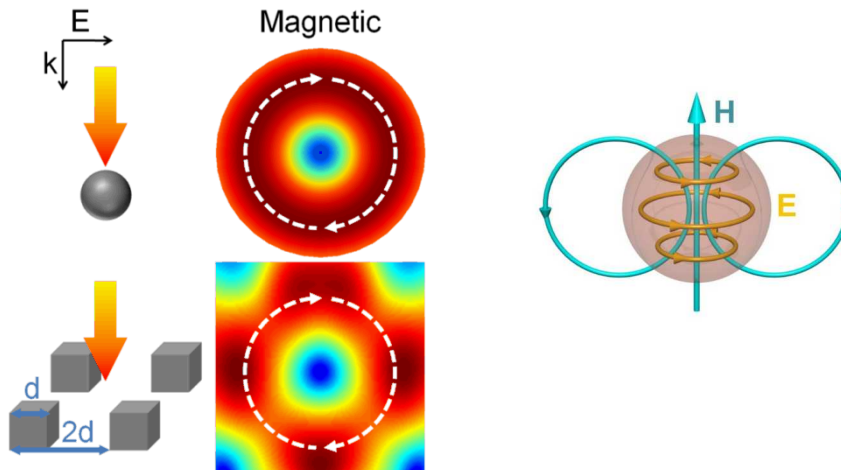
Creating a Magnetic Mirror from a Collection of Magnetic Dipoles

A perfect magnetic conductor does not exist in nature



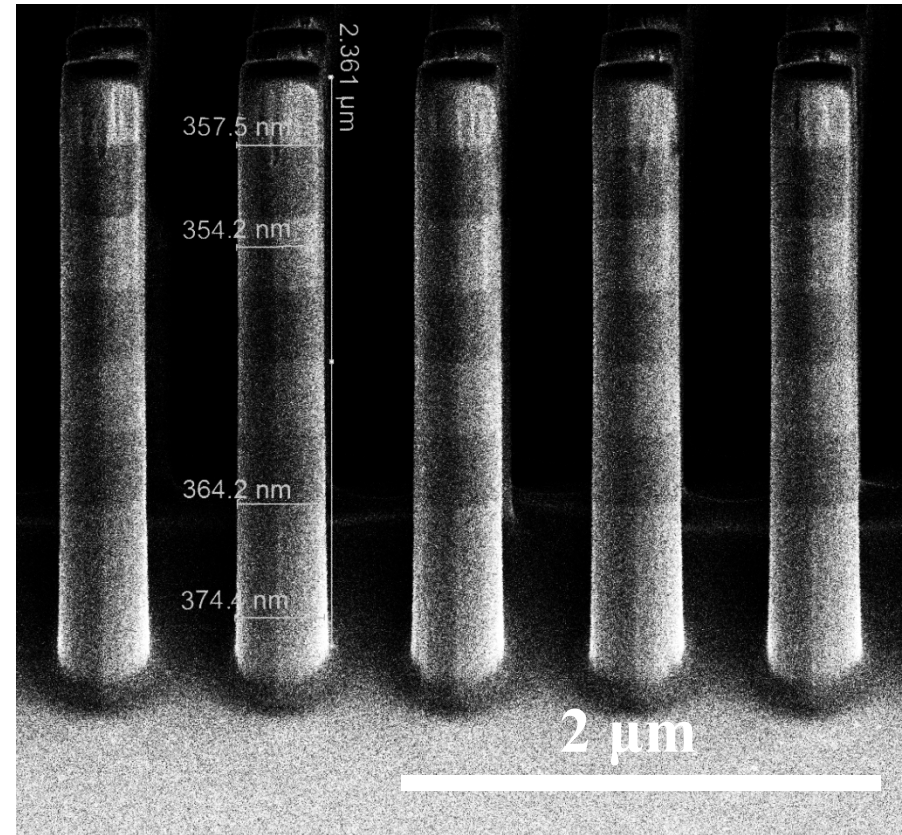
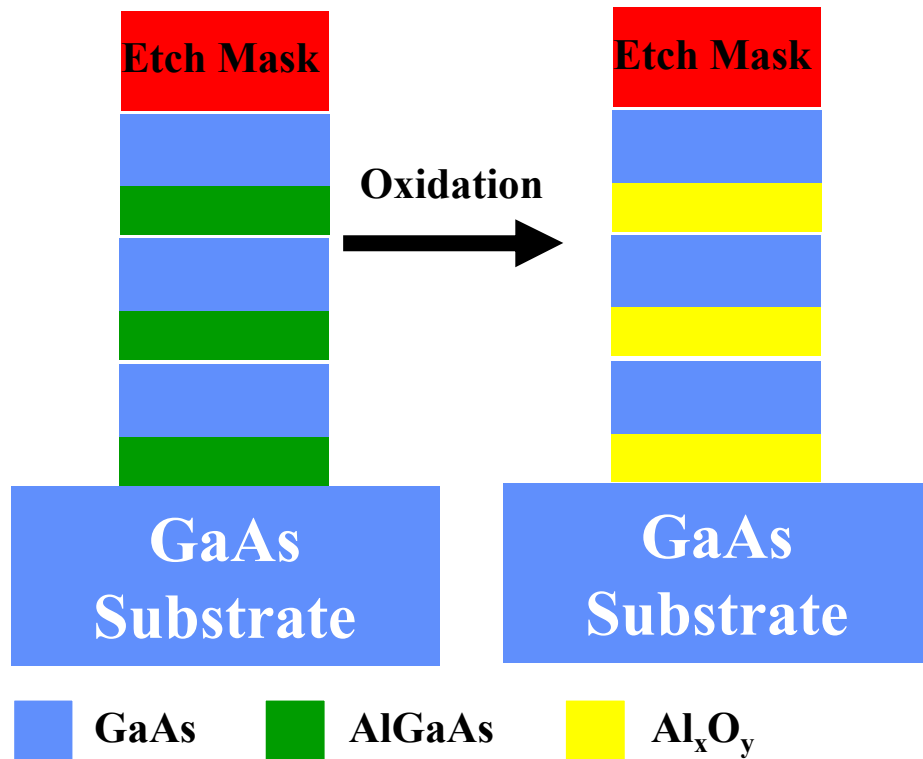
Because the magnetic dipole responds in phase with the electric field, this represents an **artificial magnetic conductor**

We can create magnetic dipoles with Dielectric Resonators



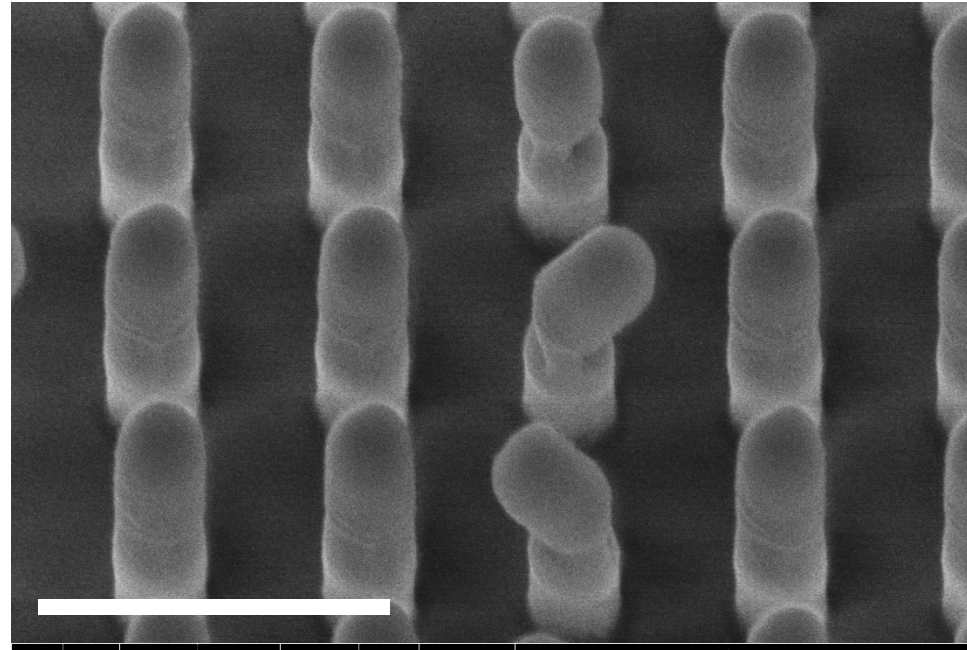
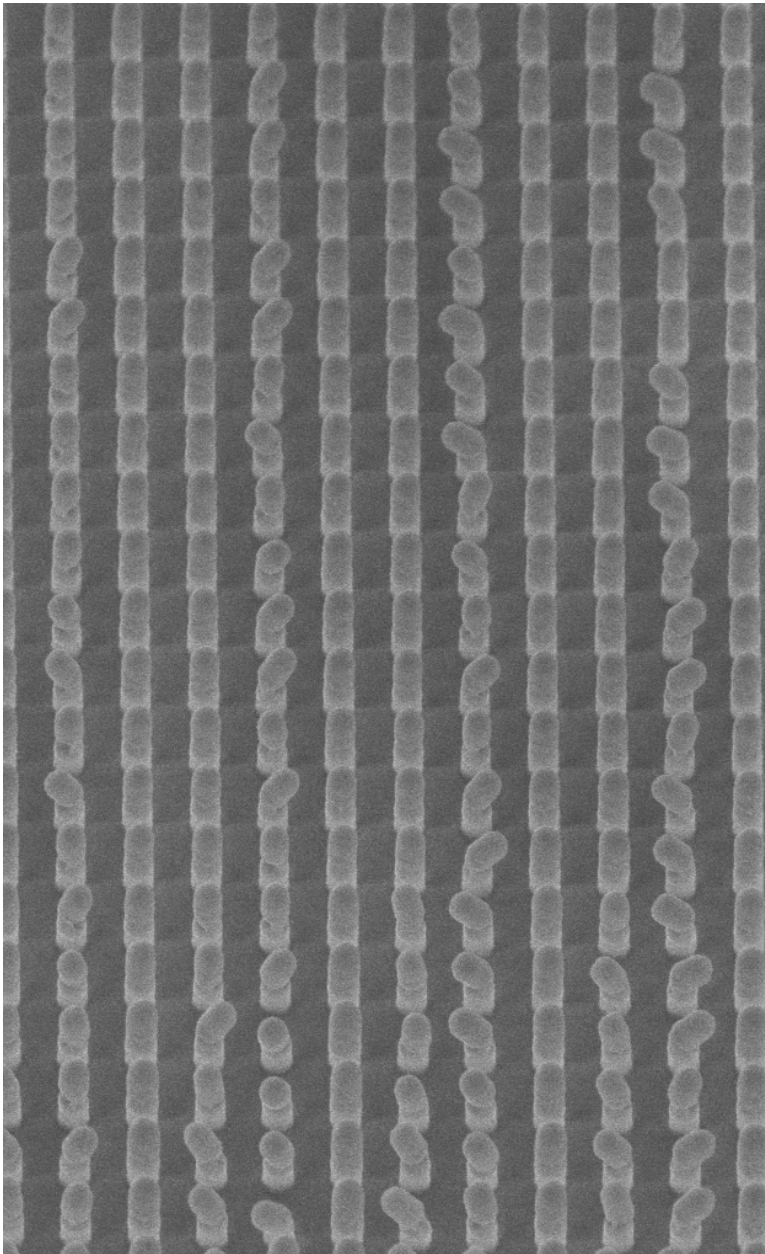
Multilayer III-V Dielectric Metamaterials

Epitaxially grown multi-layer
GaAs/AlGaAs



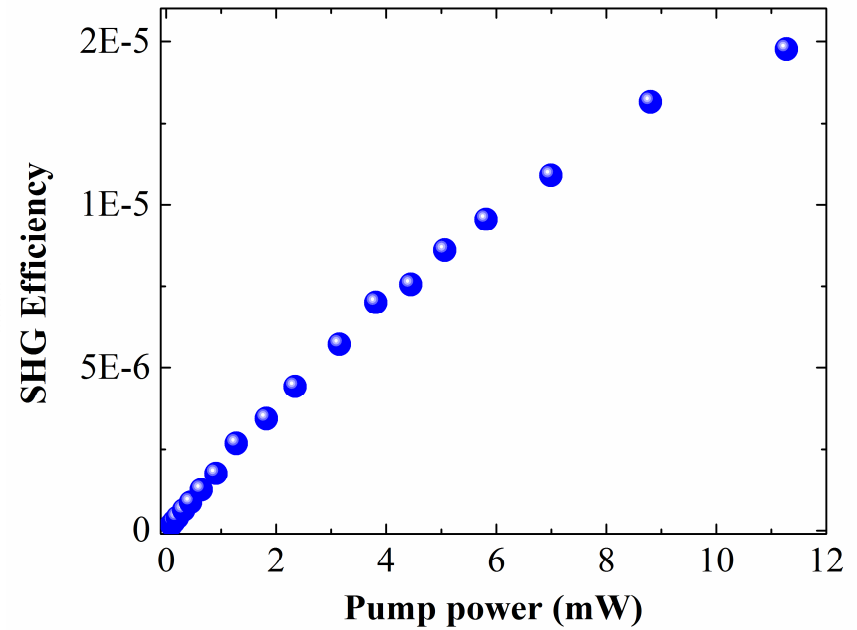
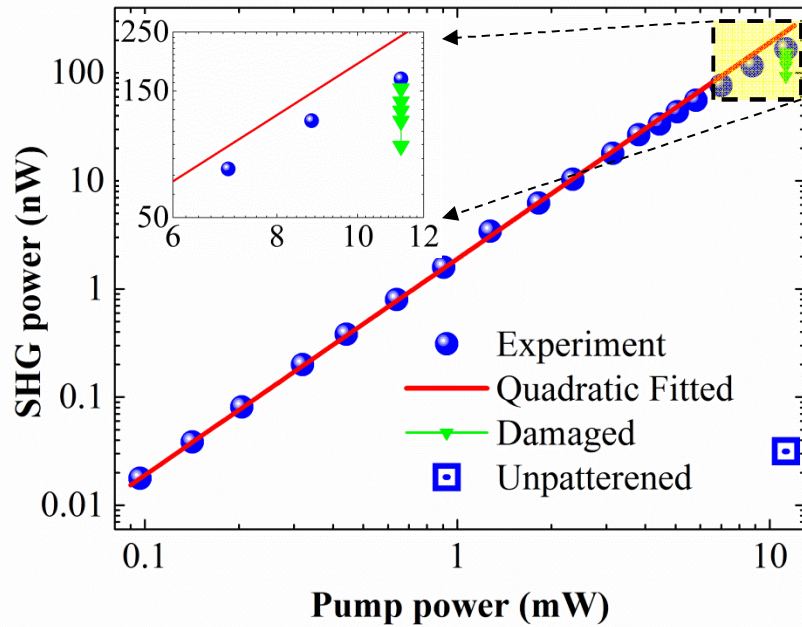


Sample damaged by strong pump and SEM images showing damage.



**Low damage threshold, maybe
due to etching induced defect
on the surface.**

Power Dependence



Effect of Absorption on SHG

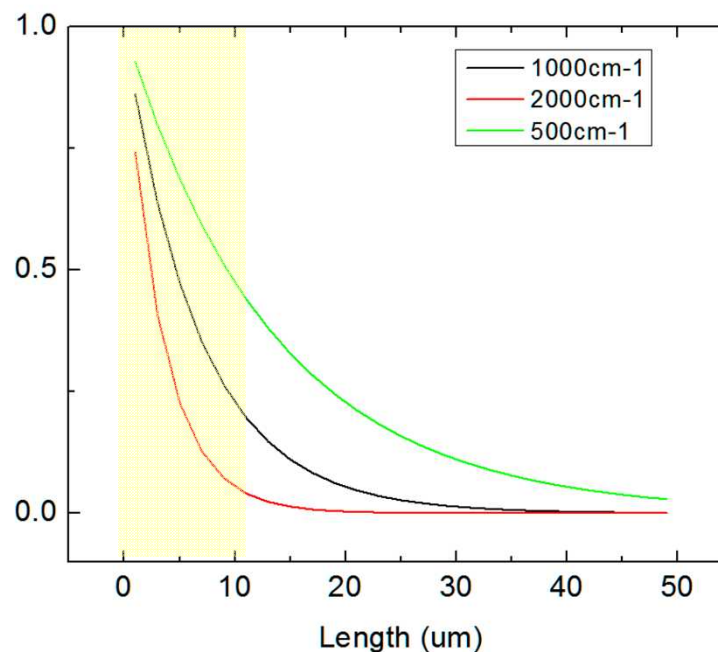
$$E(2\omega) \propto e^{\frac{-\alpha_{2\omega}l}{2}} \int_0^l e^{\alpha'z} dz, \quad \alpha' = \alpha_{\omega} - \frac{\alpha_{2\omega}}{2}$$

$$I_{2\omega}(l) \propto e^{-\alpha_{2\omega}l} \frac{(e^{-\alpha'l} - 1)^2}{\alpha'^2}$$

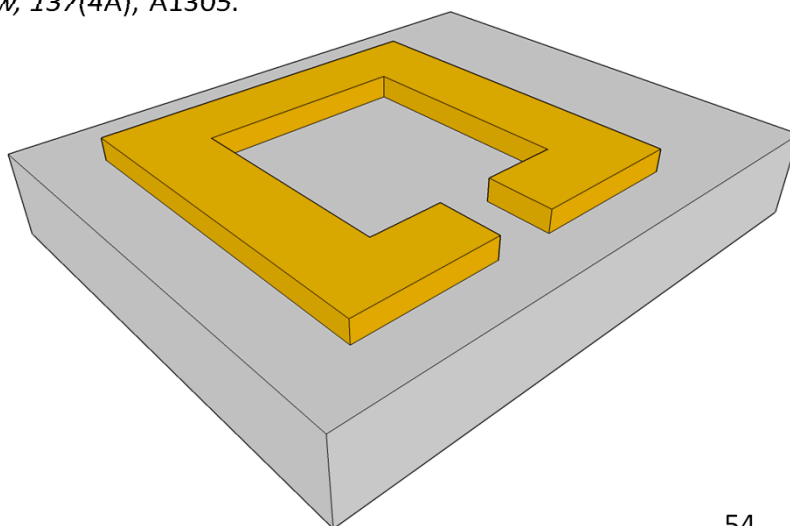
$$\alpha_{\omega} \approx \alpha_{2\omega} \approx \alpha$$

$$I_{2\omega}(l) \propto e^{-\alpha l} \frac{\left(e^{\frac{-\alpha l}{2}} - 1\right)^2}{\left(\frac{-\alpha l}{2}\right)^2}$$

Boyd, Ashkin, Dziedzic, & Kleinman, (1965).
Physical Review, 137(4A), A1305.

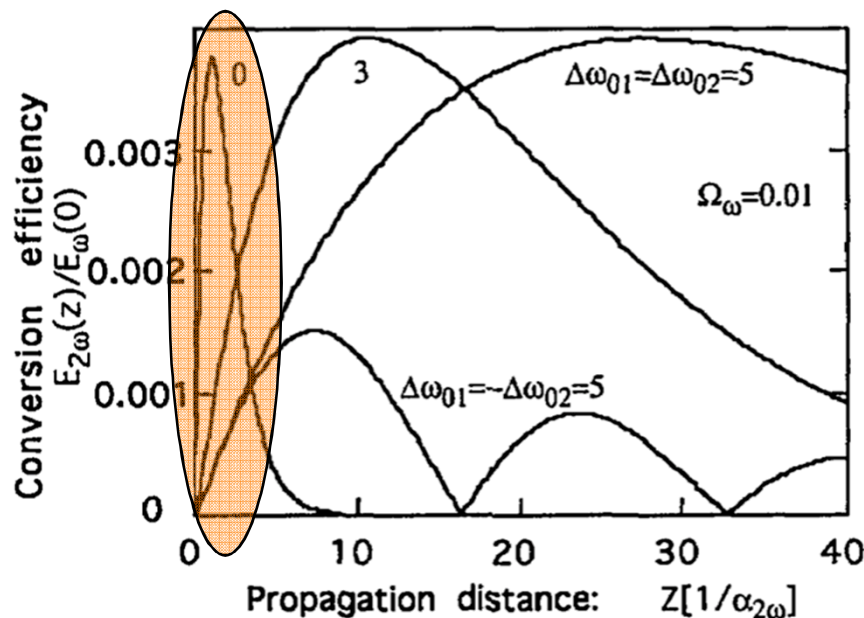


For $\alpha \sim 1000 \text{ cm}^{-1}$, “effective length” ($Q \times L$)
 needs to be < few microns



$Q \sim 10$
 Field decay length (L) $\sim 200 \text{ nm}$
 $Q \times L \sim 2 \mu\text{m} \dots$

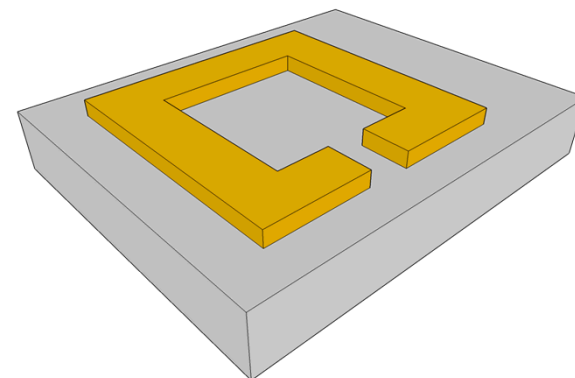
Effect of Absorption on SHG (unavoidable when using resonant $\chi^{(2)}$)



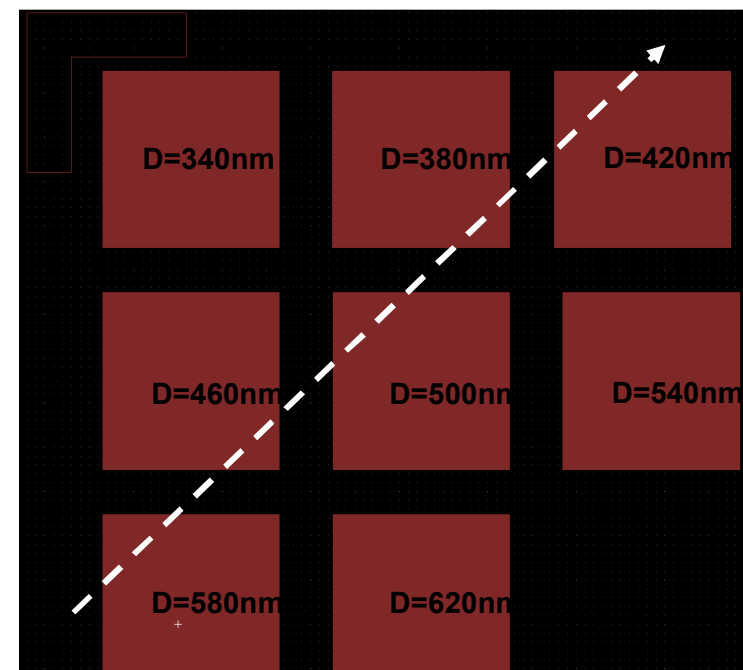
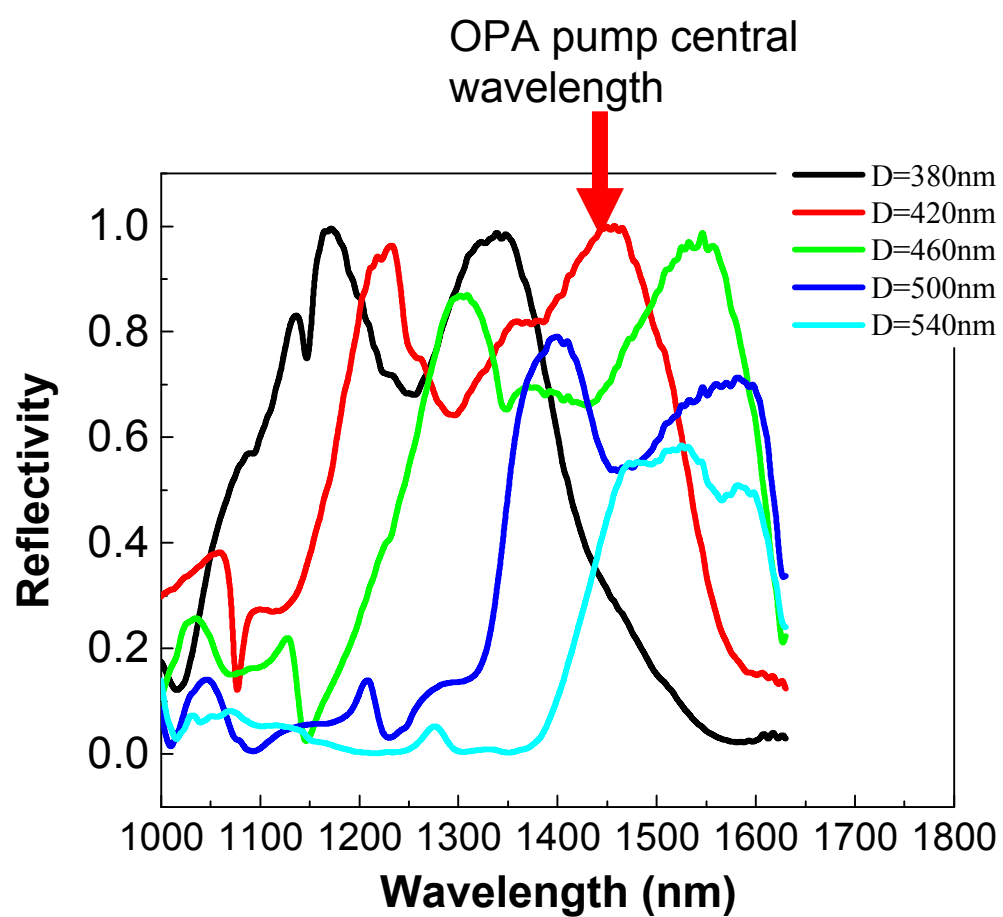
Almogy&Yariv, *Optics Letters* (1994)

For $\alpha \sim 1000 \text{ cm}^{-1}$ ($1/\alpha \sim 10 \mu\text{m}$),
"effective length" ($Q \times L$) needs to be $< \sim 10$ microns

Dealt first by Boyd, Ashkin, Dziedzic, & Kleinman, (1965).
Physical Review, 137(4A), A1305.



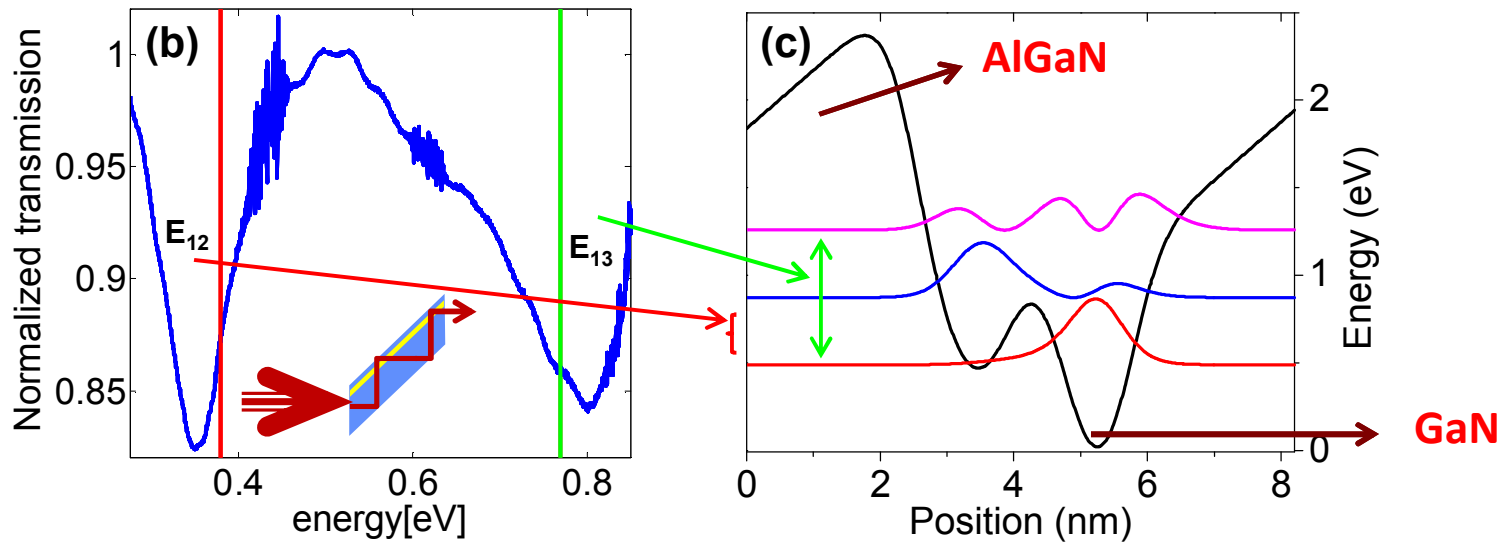
"Cavity" with $Q \sim 10$
 Field decay length (L) $\sim 200 \text{ nm}$
 $Q \times L \sim 2 \mu\text{m} \dots \gg \text{OK},$
We cannot gain too much more by increasing Q !





Omri Wolf

SHG ($3.2\mu\text{m} > 1.6\mu\text{m}$) Using AlGaN/GaN QWs



In a III-N heterostructure, metamaterials increase efficiency by over 2 orders of magnitude